

SIMULATION DES DETECTEURS GERMANIUM

Bart Bruyneel

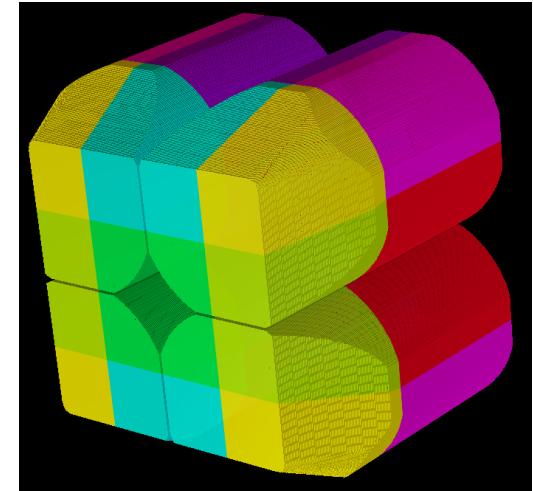
CEA Saclay, France



17/06/2013 la Journée de la simulation, Orsay

ADL 3.0

36 fold segm. AGATA crystal



Segmented Clover detector

Overview

- Intro on AGATA & Tracking
- AGATA Detector Library « ADL 3.0»
- Weighting potential
 - Ramo Theorem
 - Time dependent weighting potentials
- Mobilities in Germanium
- Correction for neutron damage

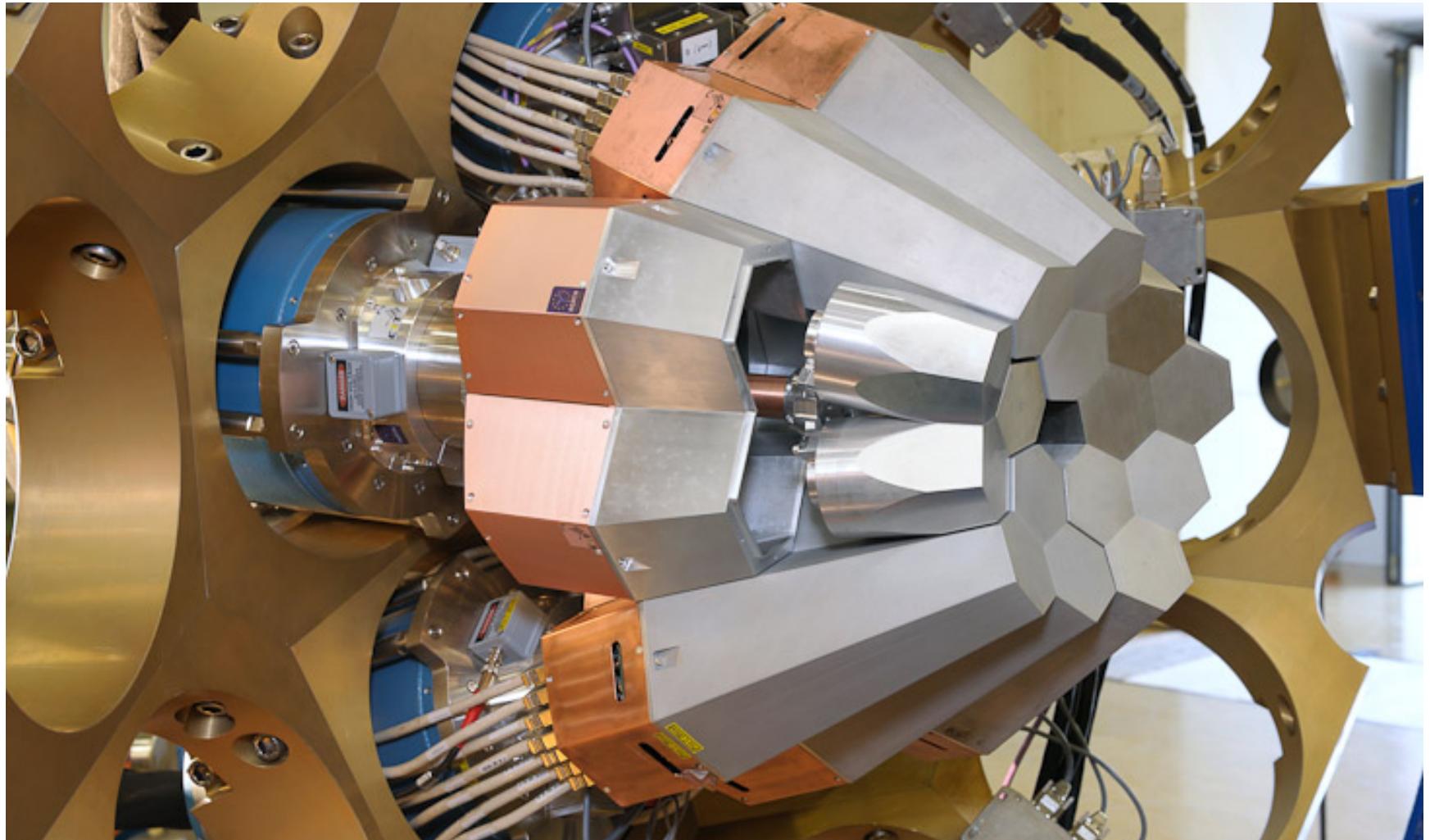


WHY ADL ?

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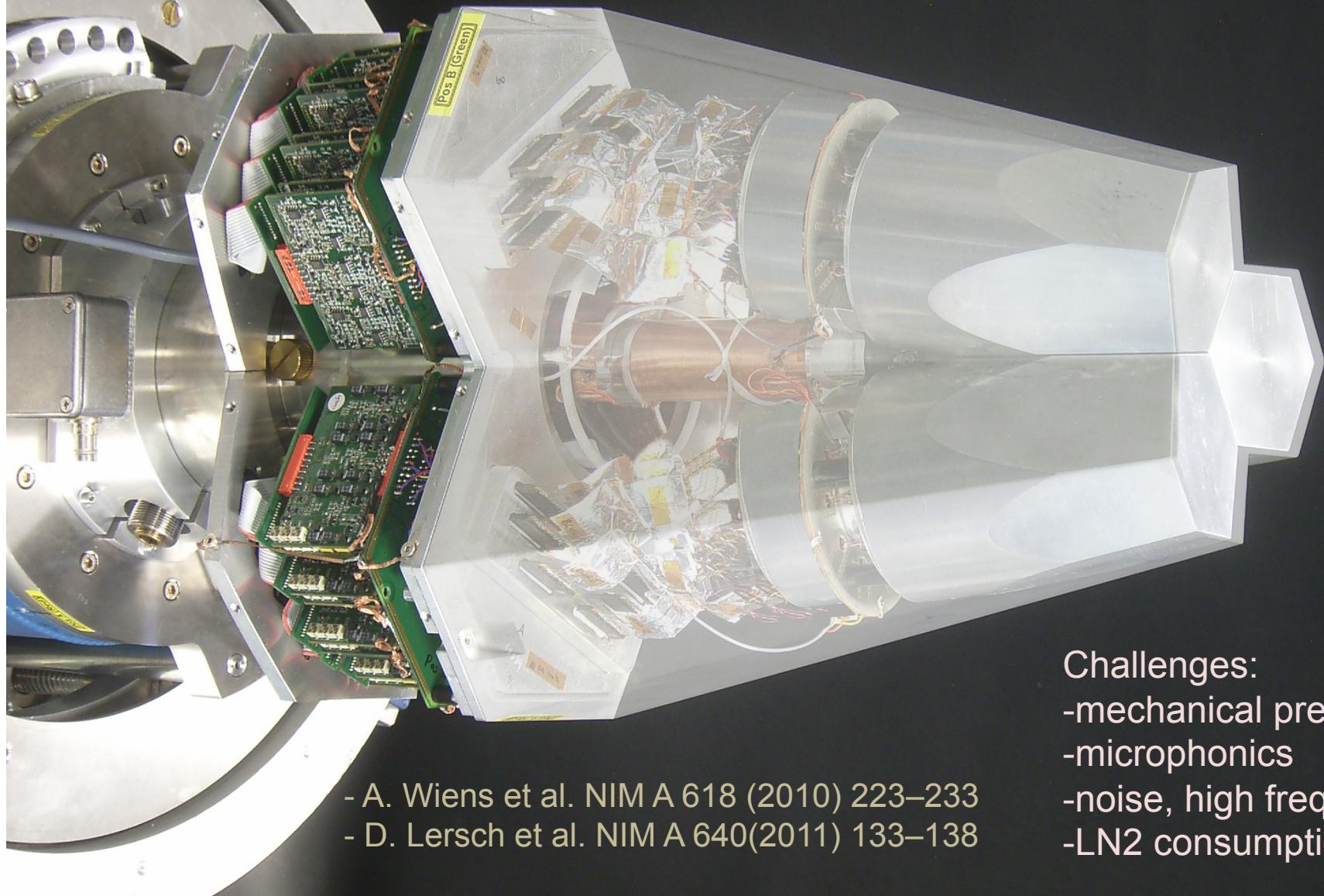


The Advanced γ Tracking Array “AGATA”



Asymmetric AGATA Tripel Cryostat

-integration of 111 high resolution spectroscopy channels
-cold FET technology for all signals

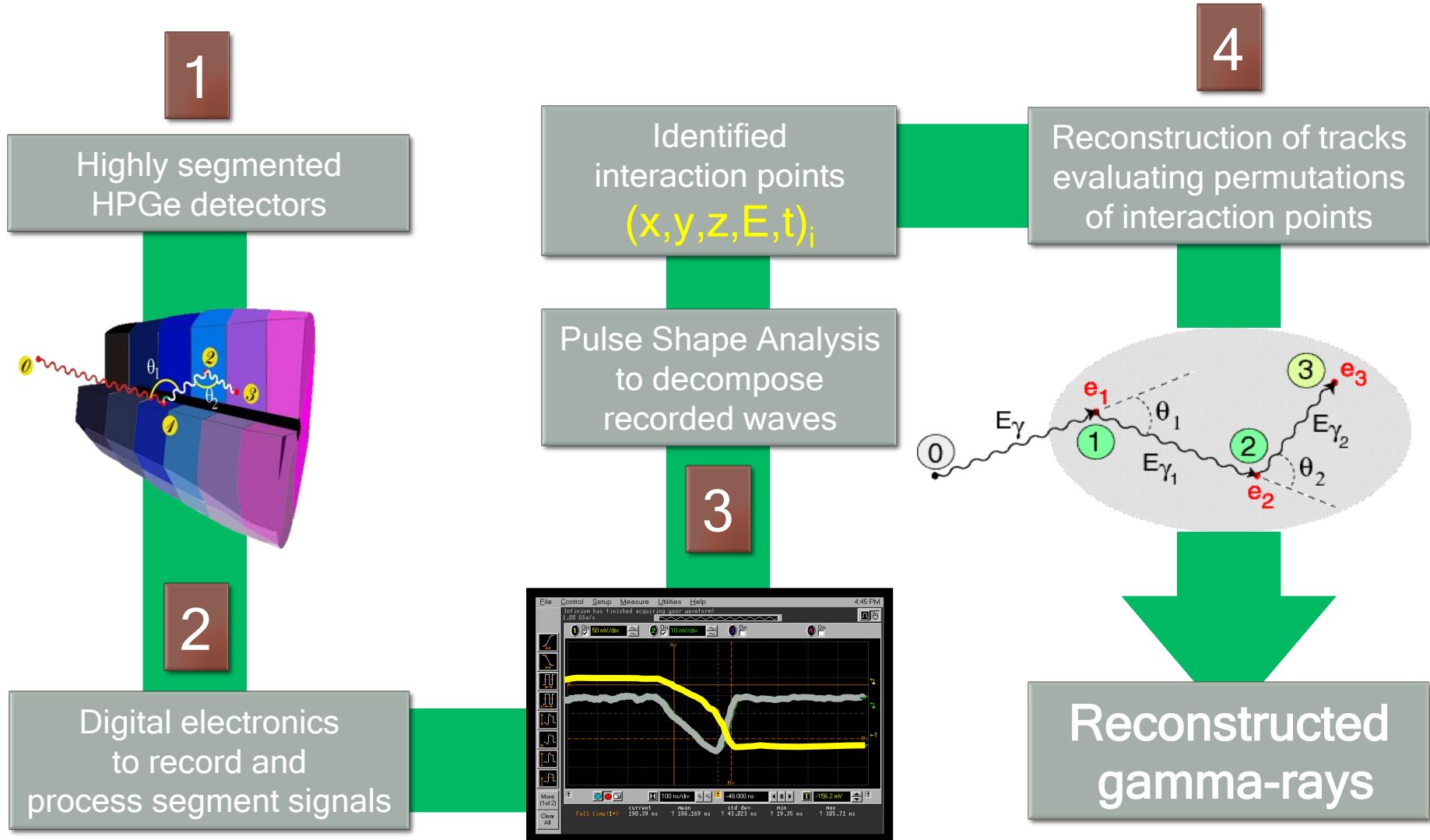


- A. Wiens et al. NIM A 618 (2010) 223–233
- D. Lersch et al. NIM A 640(2011) 133–138

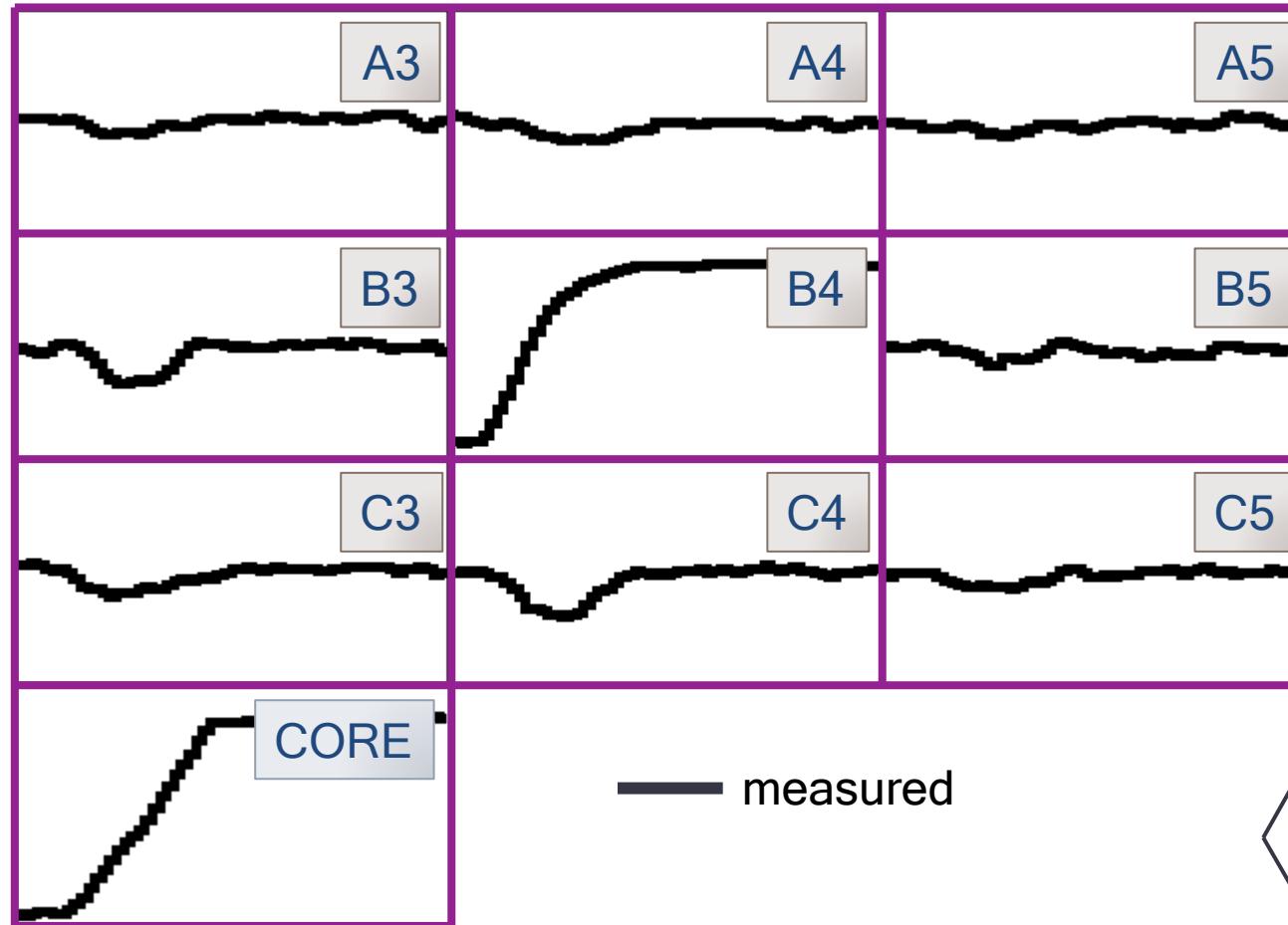
Challenges:

- mechanical precision
- microphonics
- noise, high frequencies
- LN2 consumption

AGATA & TRACKING



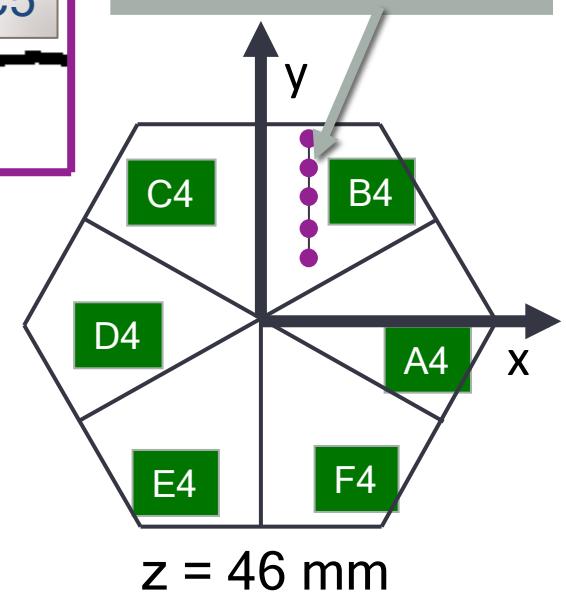
Pulse Shape Analysis Concept

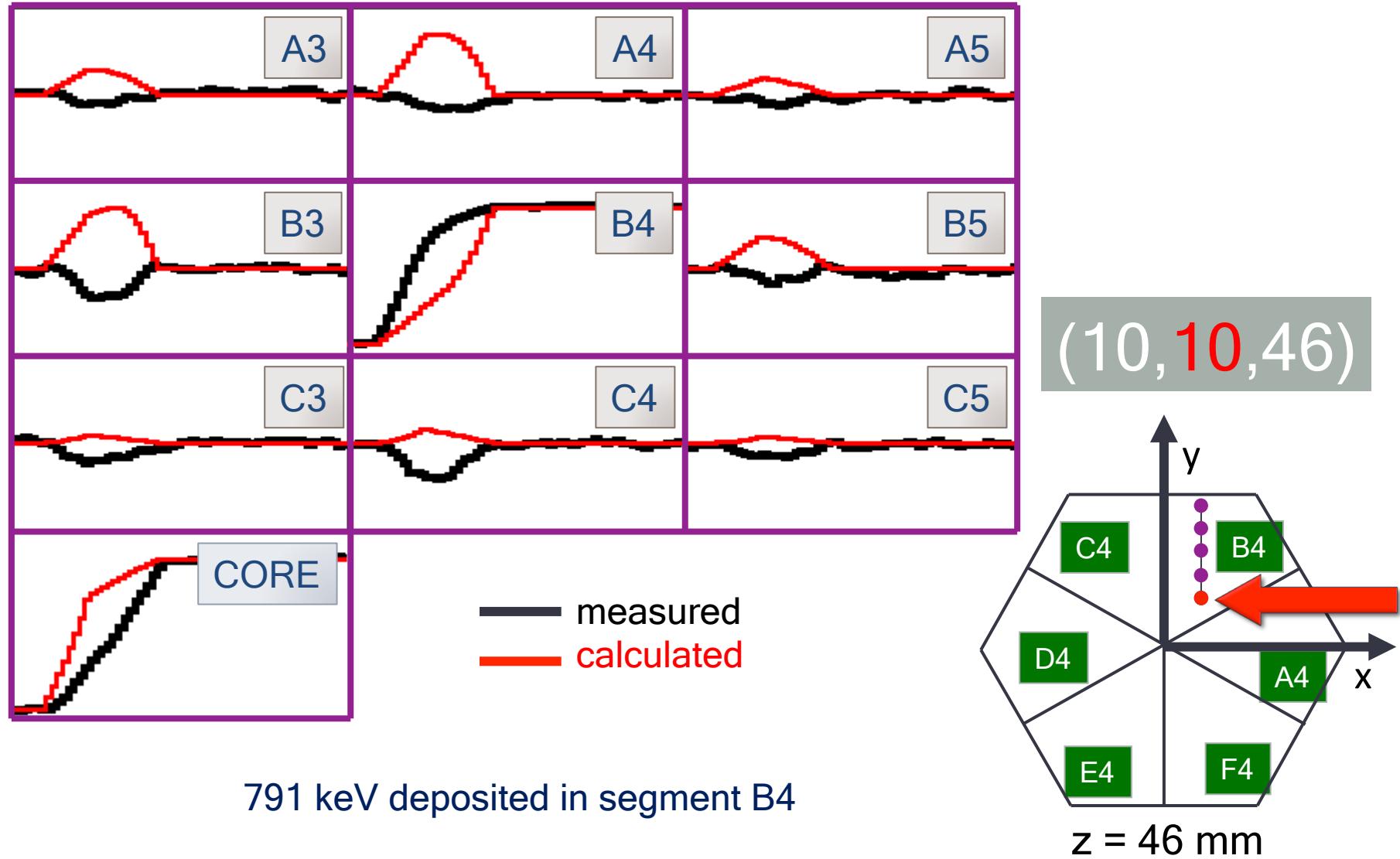


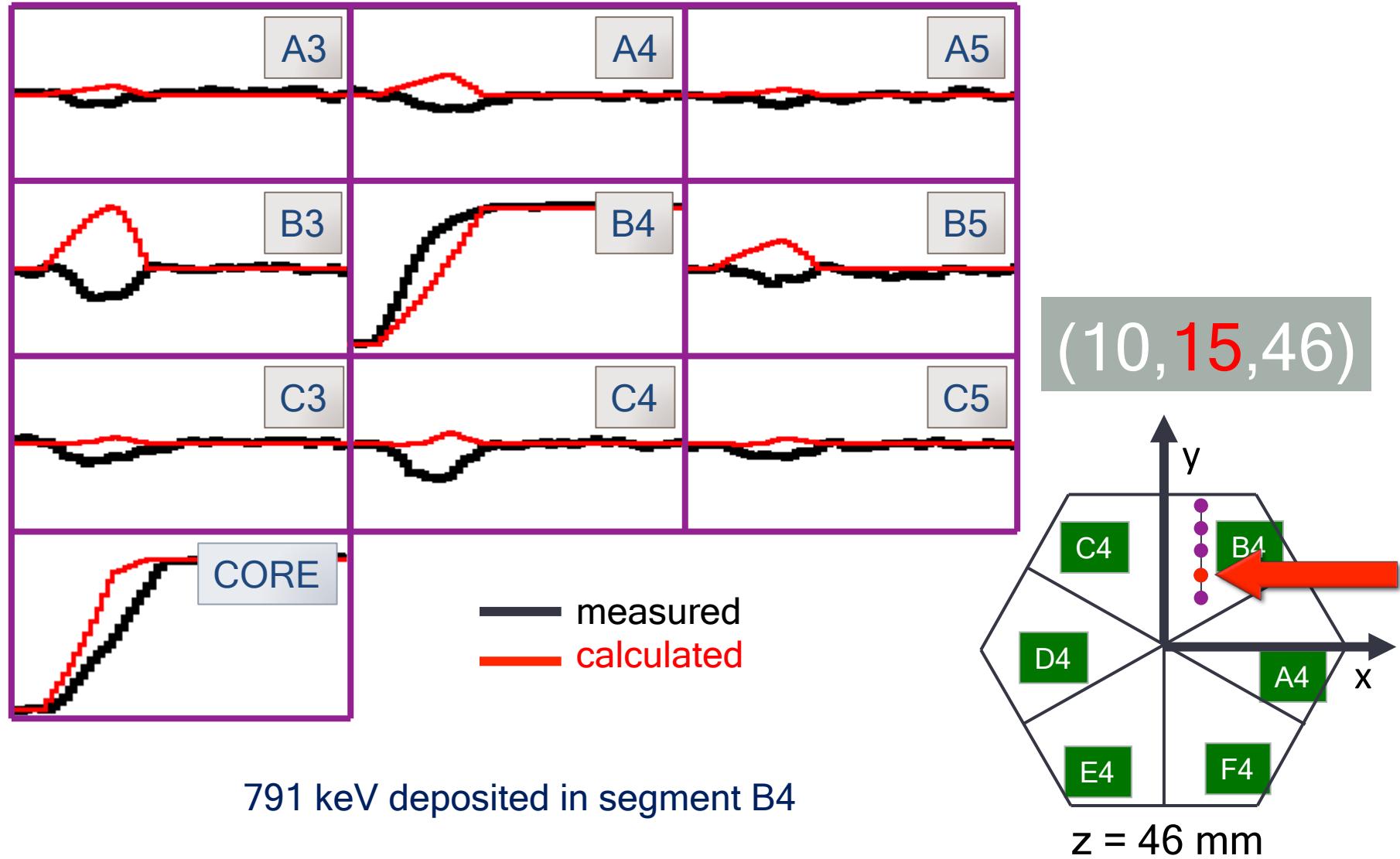
791 keV deposited in segment B4

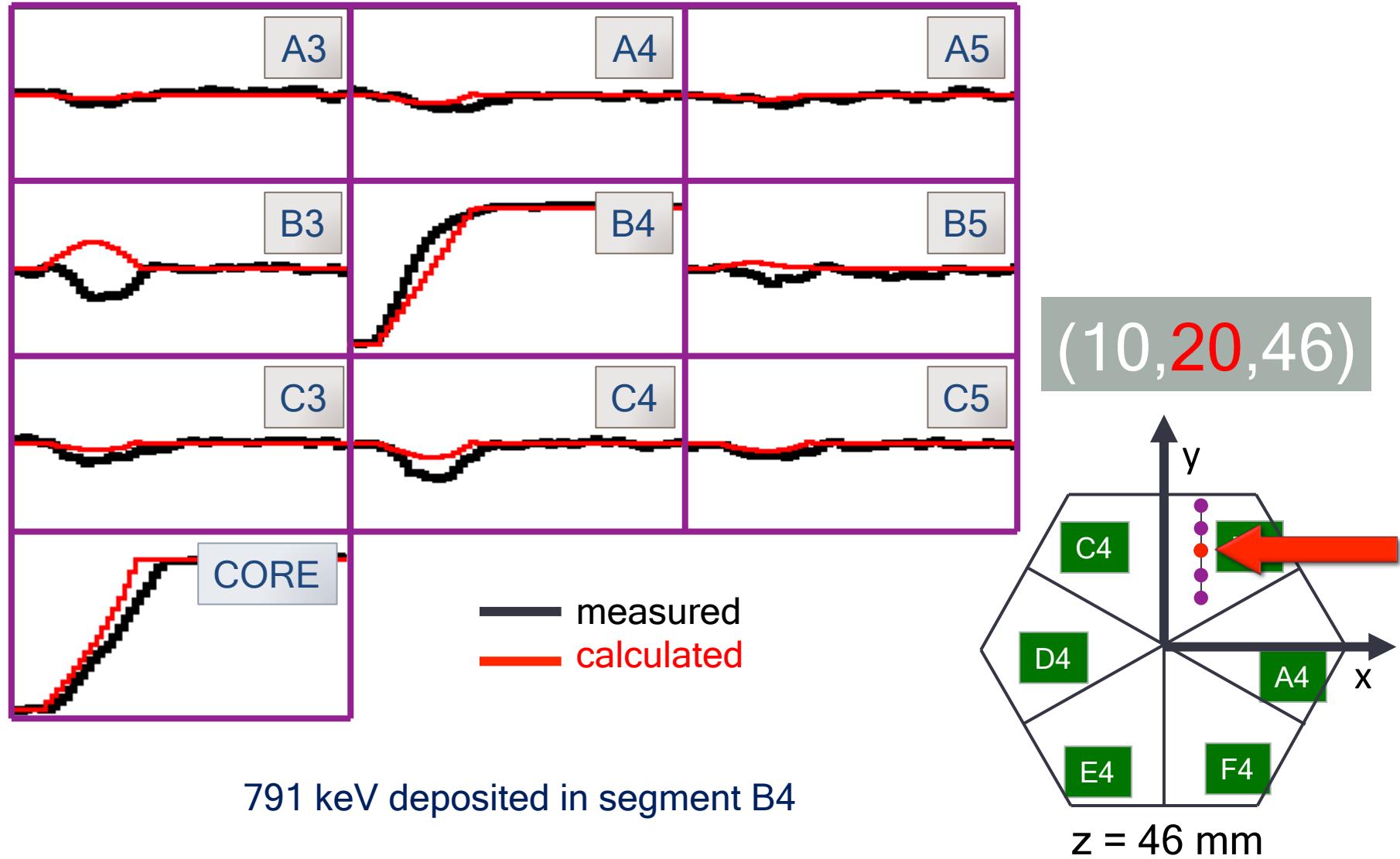
Library generation

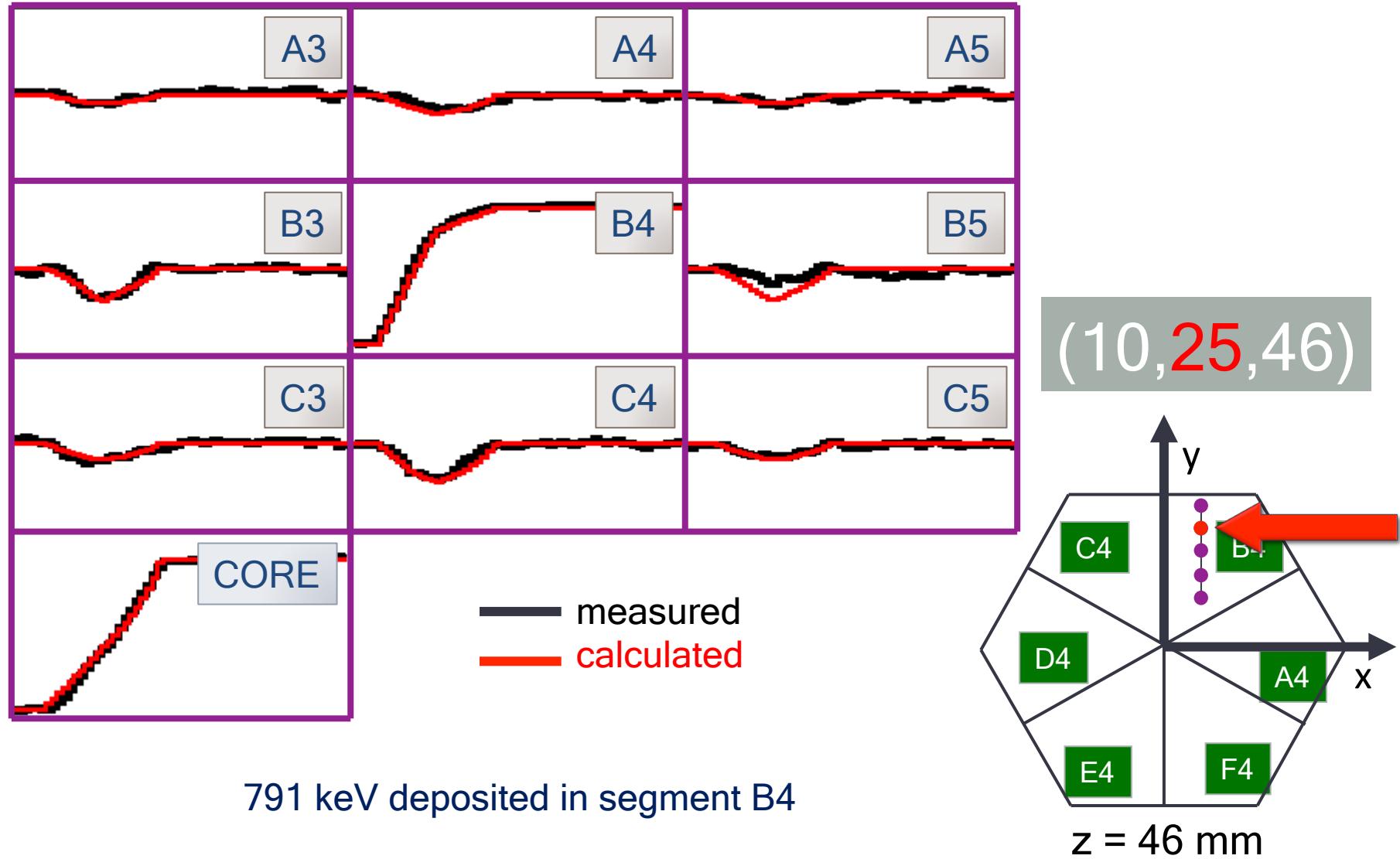
Different codes
ADL (C)
JASS (Java)
MGS (Matlab)

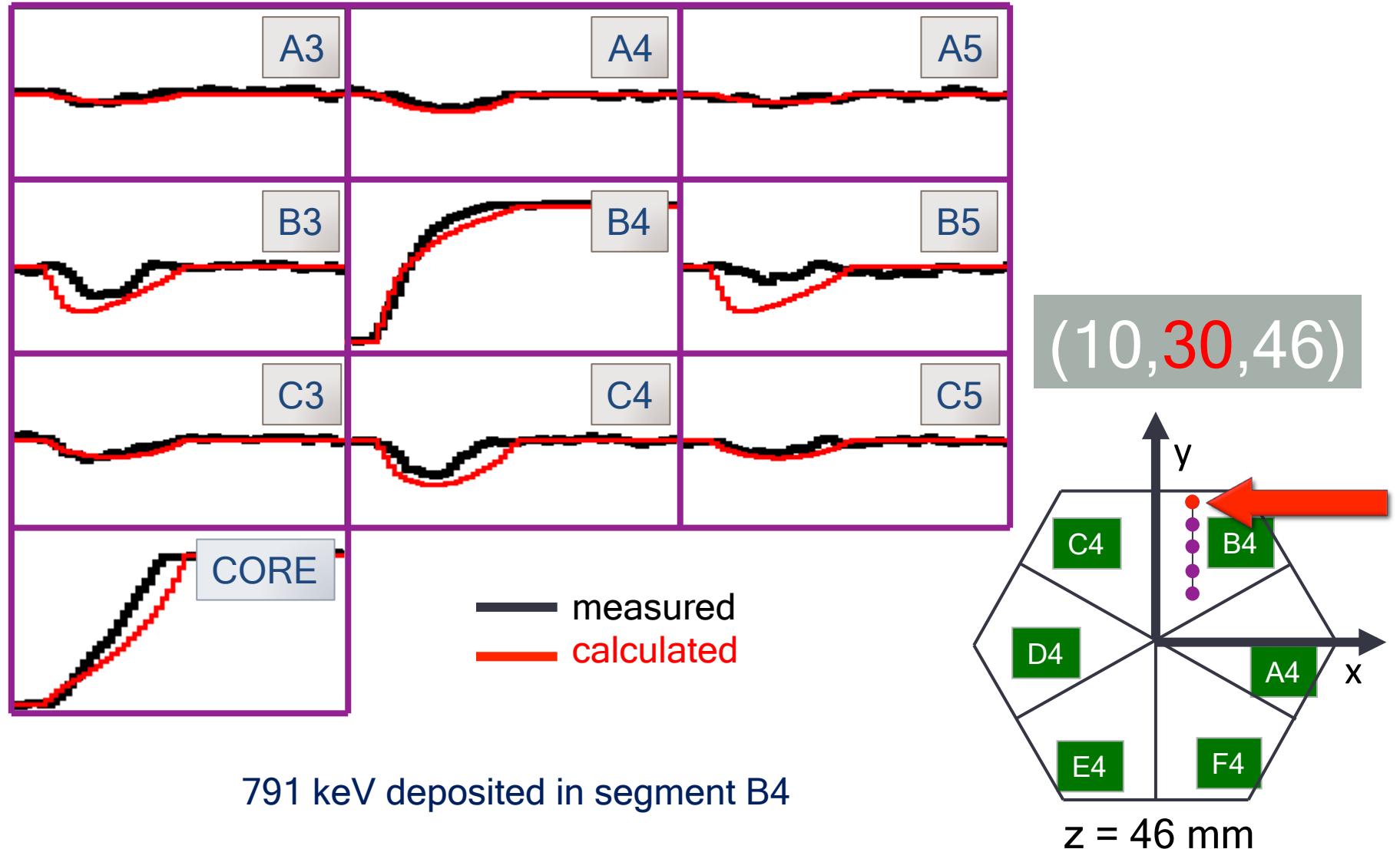








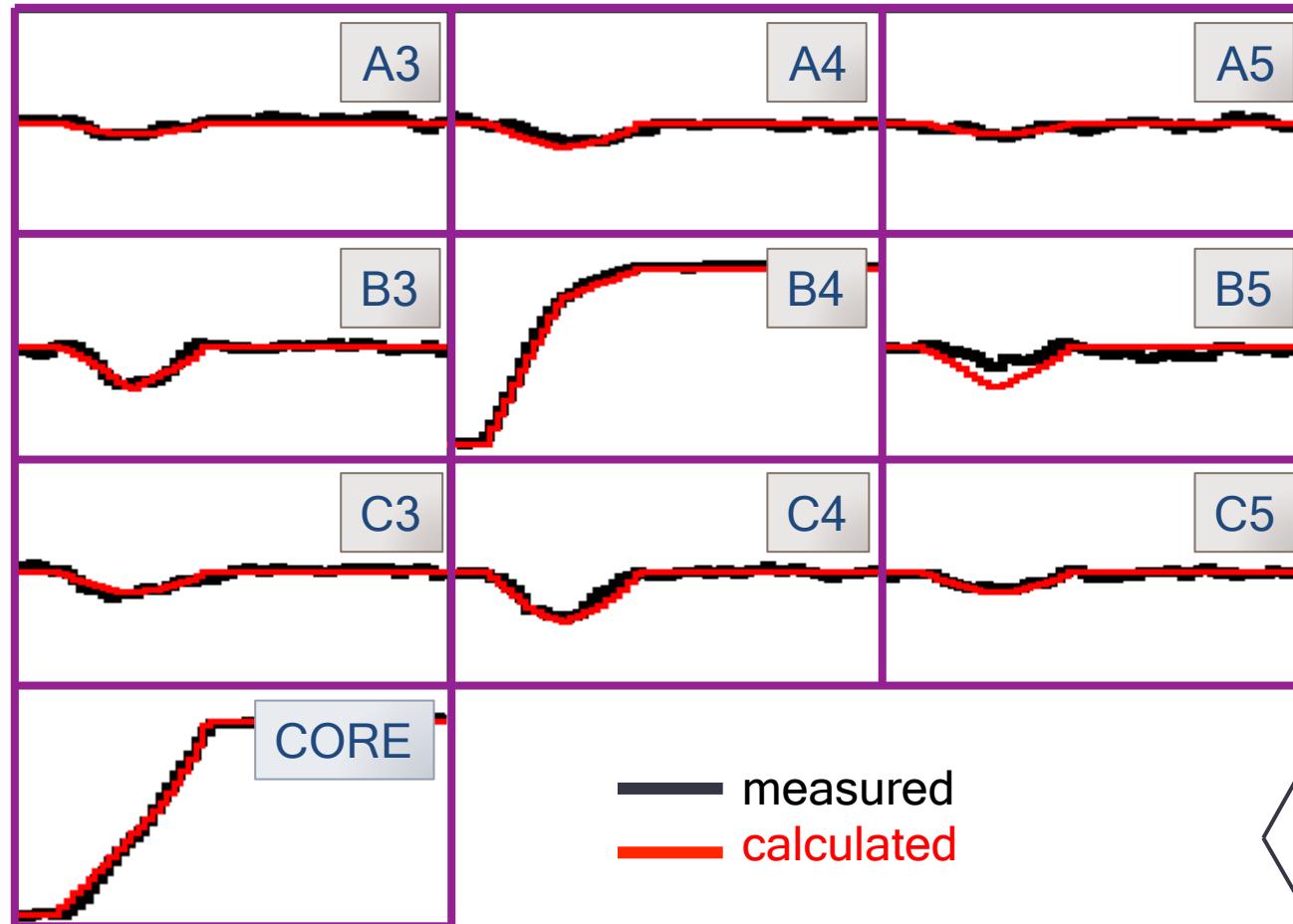




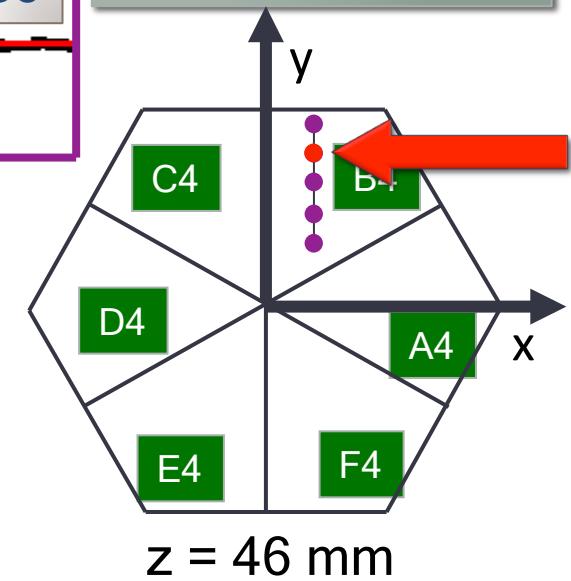
Result of *Grid Search* algorithm

R. Venturelli

(10,25,46)



791 keV deposited in segment B4

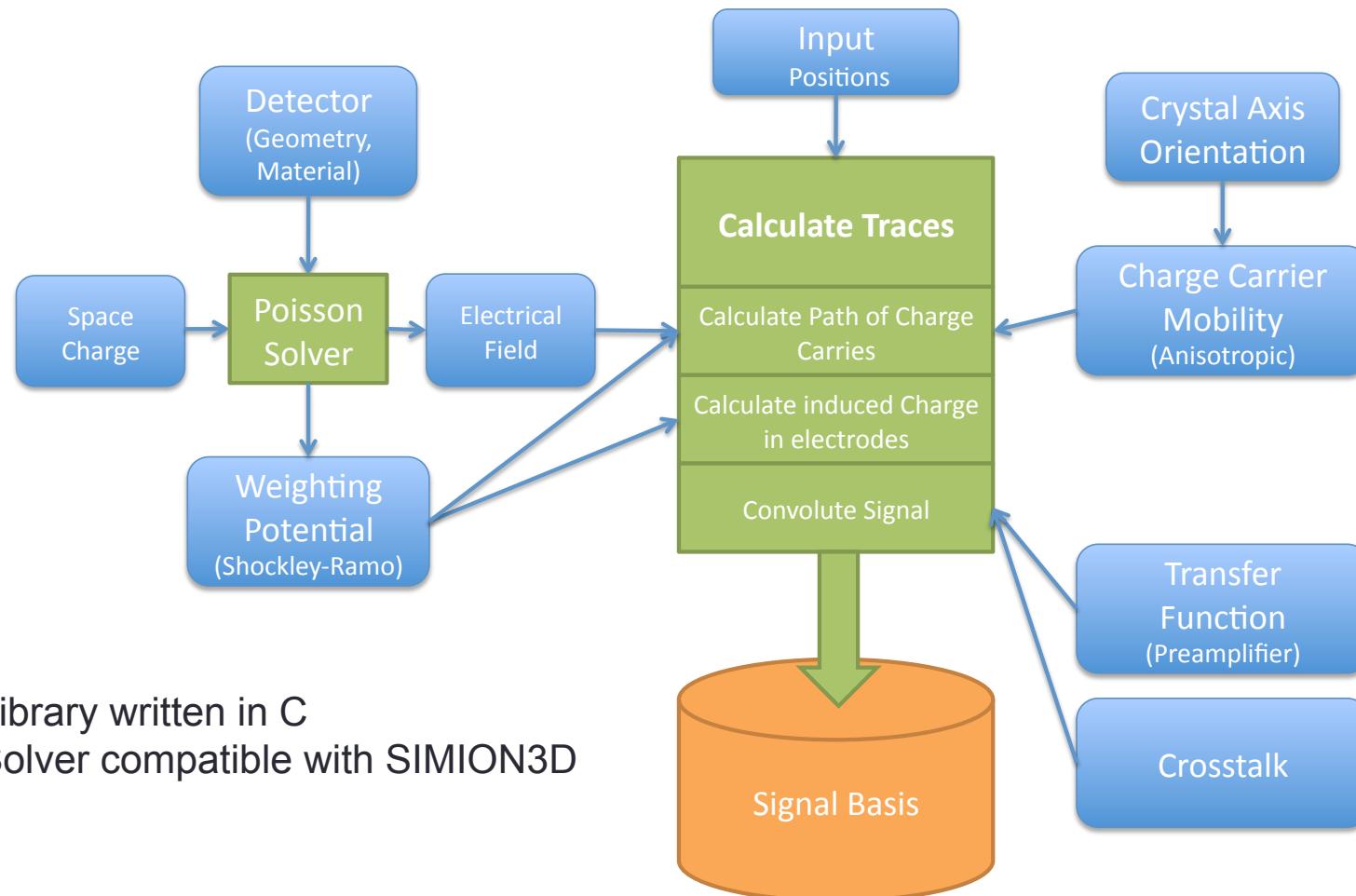


ABOUT ADL 3.0

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AGATA Detector Library “ADL”



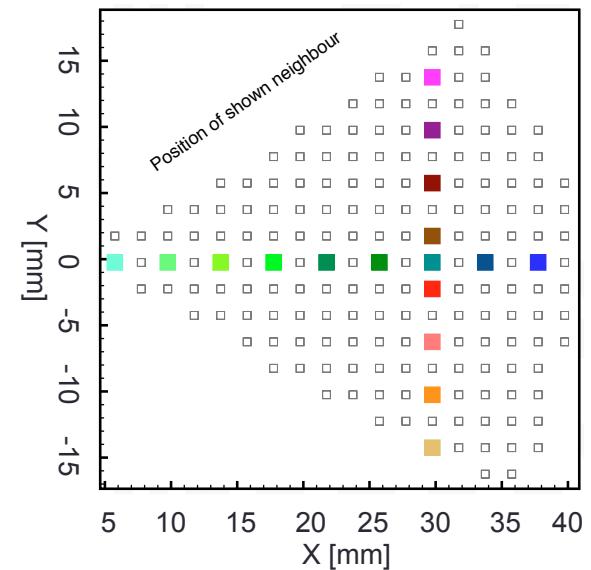
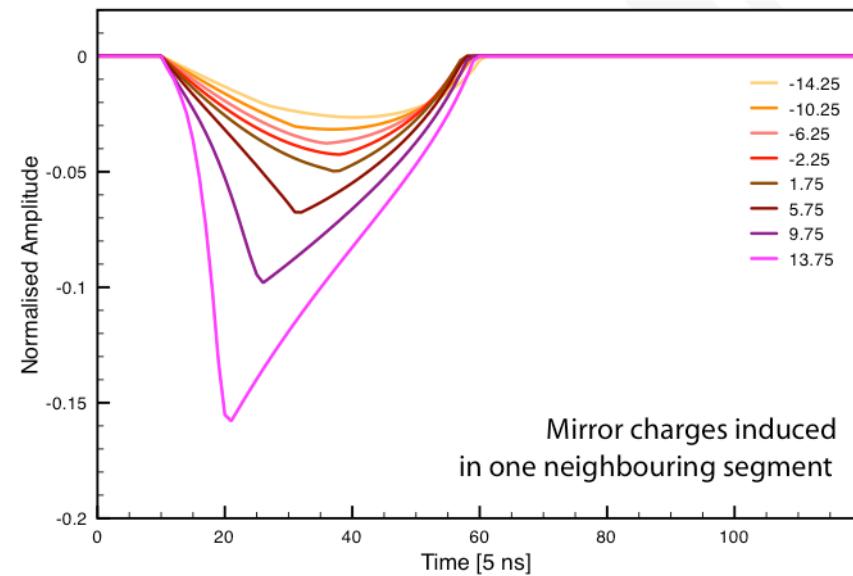
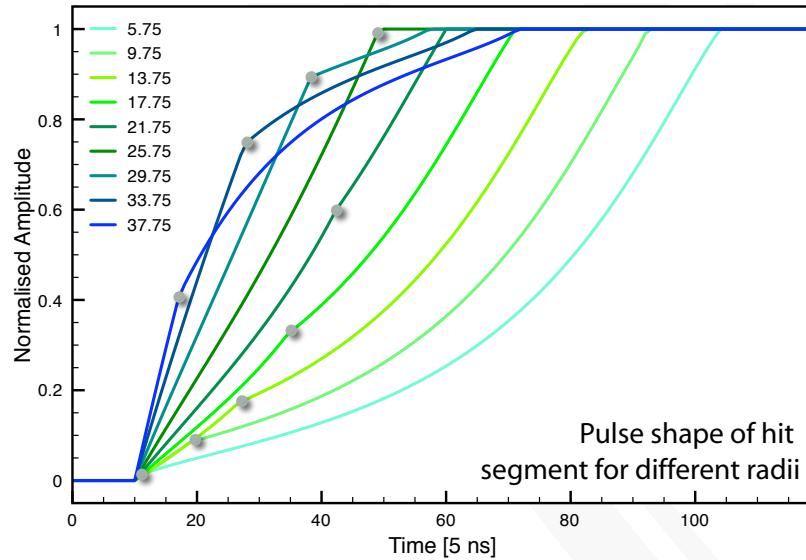
AGATA Detector Library “ADL”

EXAMPLE PROGRAM

```
1 #include "ADL.h"
2
3 int main (void) {
4     FILE *output;
5     struct ADL_EVENT *evt;
6
7     ADL_Setup("/Volumes/BEAST/AGATA/Config/Template_ADL.txt");
8     ADL_Status();
9
10    //lets create a new event structure:
11    evt = new_event();
12    //Fill in the Hit Pattern (HP):
13    evt->HP.Eint[0]=10.0;      //Energy of interaction 0 (we only simulate a single interaction here)
14    evt->HP.T0= 0.010;        //Time the interaction occurs in the trace
15    evt->HP.Pos[0][0]=2.0;    //Position where this interaction occurs
16    evt->HP.Pos[0][1]=2.0;
17    evt->HP.Pos[0][2]=8.0;
18
19    //On basis of the HP, here the traces are generated
20    //Traces are stored in the Trace Data (TD) part of the event:
21    ADL_G_CalculateTraces(evt);
22
23    //Write the event to file:
24    output = fopen("/Volumes/BEAST/AGATA/output.txt","w");
25    ADL_G_WriteEvent(output,evt);
26    fclose(output);
27    return 0;
28 }
```

Examples: AGATA

- Signal shapes from AGATA detector as function of position
- Simulation using ADL
- (Steepest slope not always clear)
- (remark: segment preamps are inverting)



WEIGHTING POTENTIALS

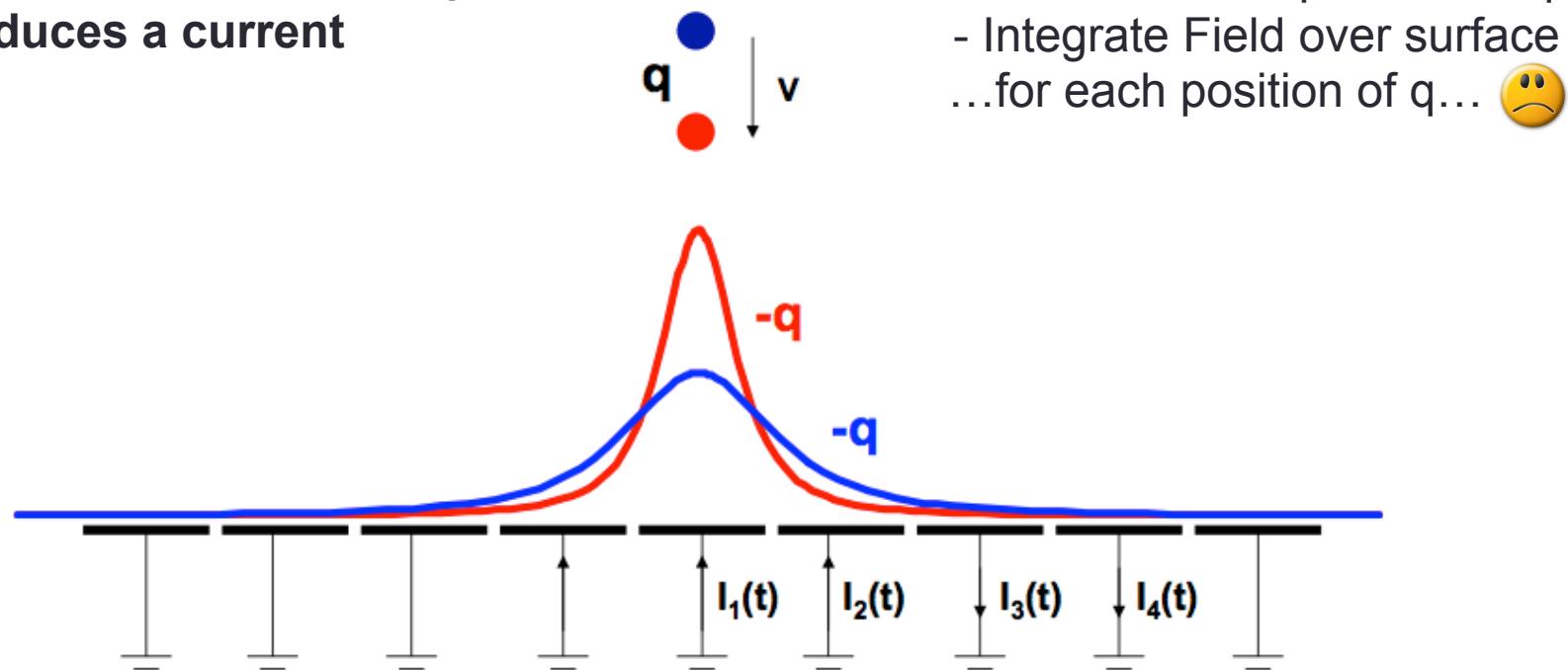
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Principle of Signal induction

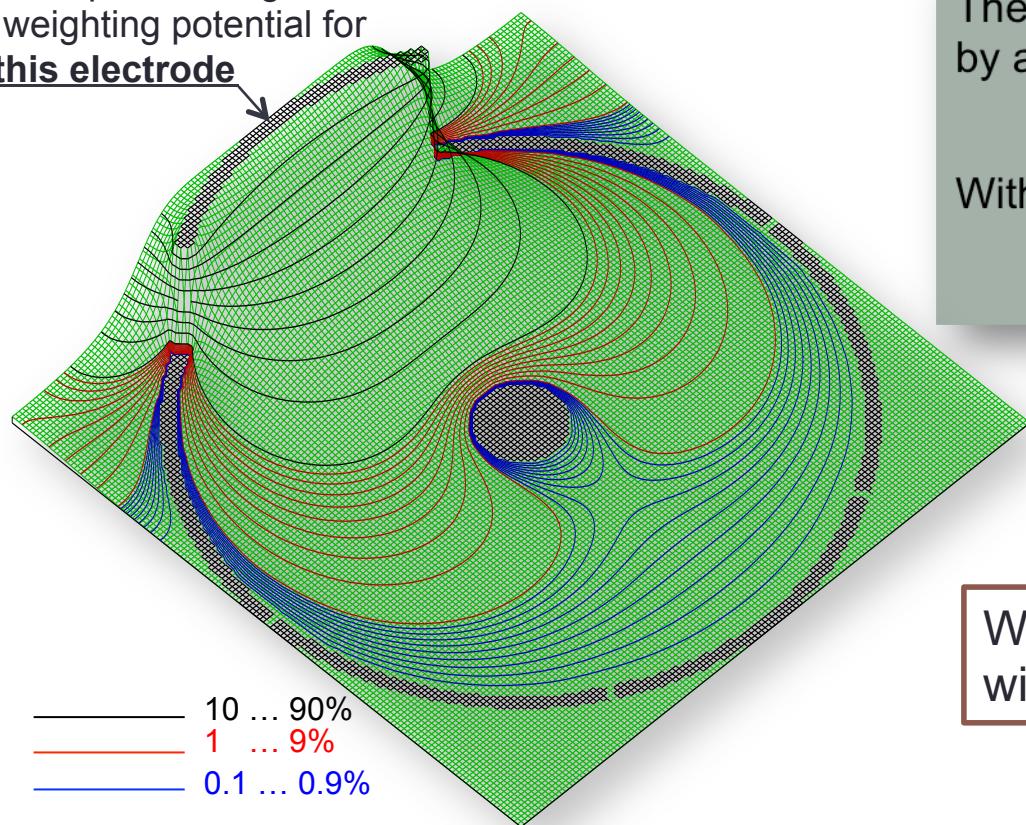
- A point **charge q** at distance z_0 above a **grounded metal plate** induces an image charge
- If the plate is segmented, The **movement of charge q induces a current**

- To calculate Induced charge:
 - Solve Field for position of q
 - Integrate Field over surface
 - ...for each position of q ... 😞



Shockley – Ramo theorem

Example - 6x segm. coaxial detector:
weighting potential for
this electrode



The induced charge Q_{qi} on electrode i by a point charge q located at x_0 is

$$Q_{qi} = -q \cdot \psi_i(\vec{x}_0)$$

With **weighting potential** ψ_i defined by

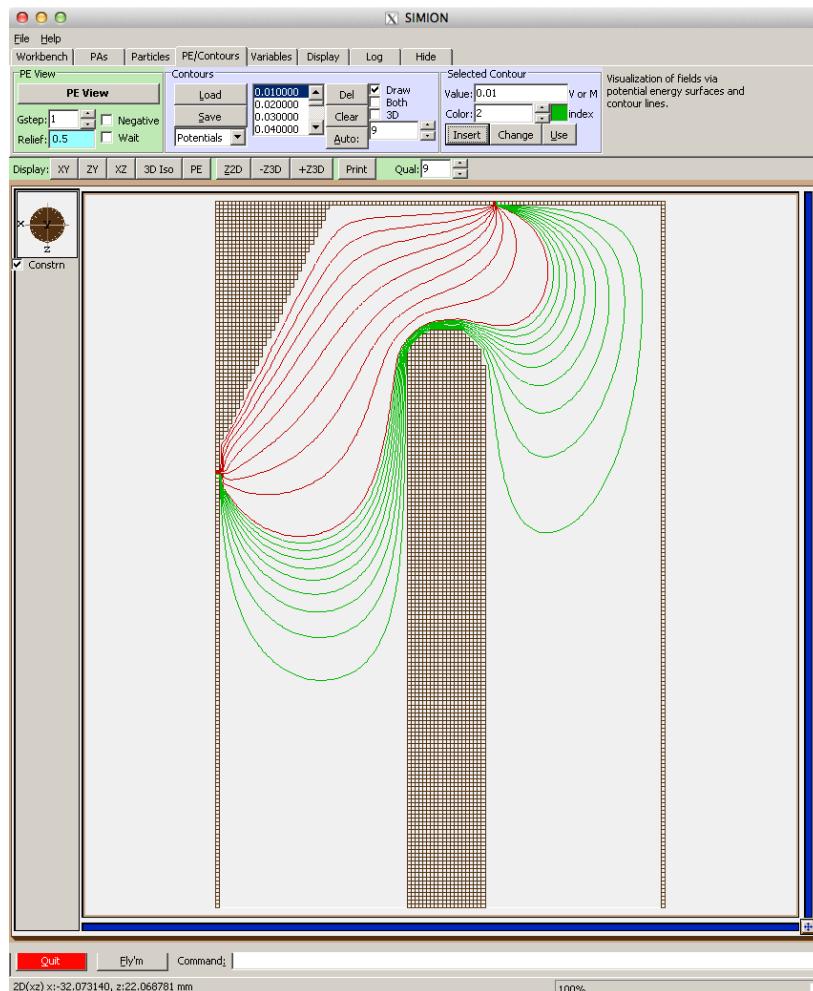
$$\nabla^2 \psi_i(\vec{x}) = 0 \quad \psi_i|_{S_j} = \delta_{i,j}$$

Weighting potentials dont change with the position of q...

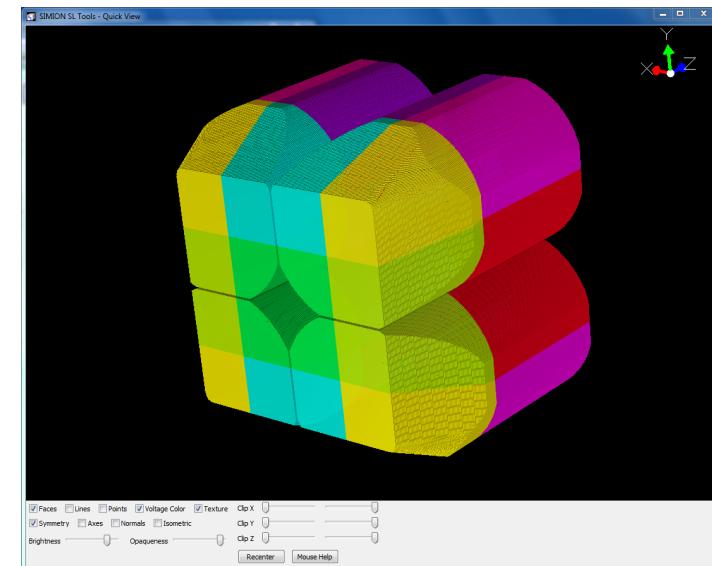
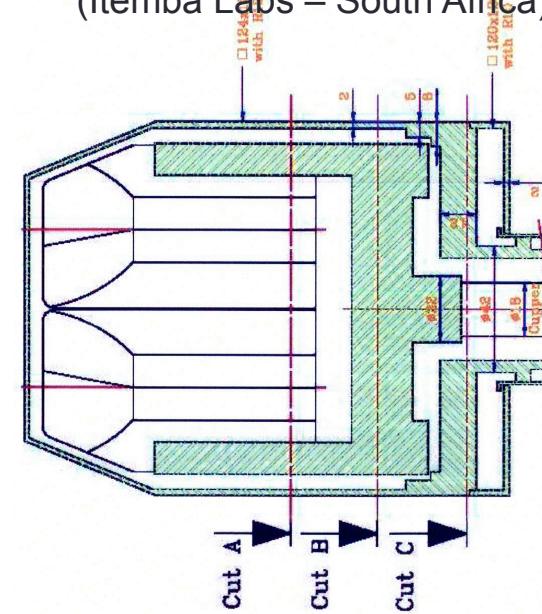


SIMION 8.0

- Tool for Ion beam line development
 - Used for visualisation in ADL
 - import geometries e.g. from CAD files



Example: clover detector (Itemba Labs – South Africa)

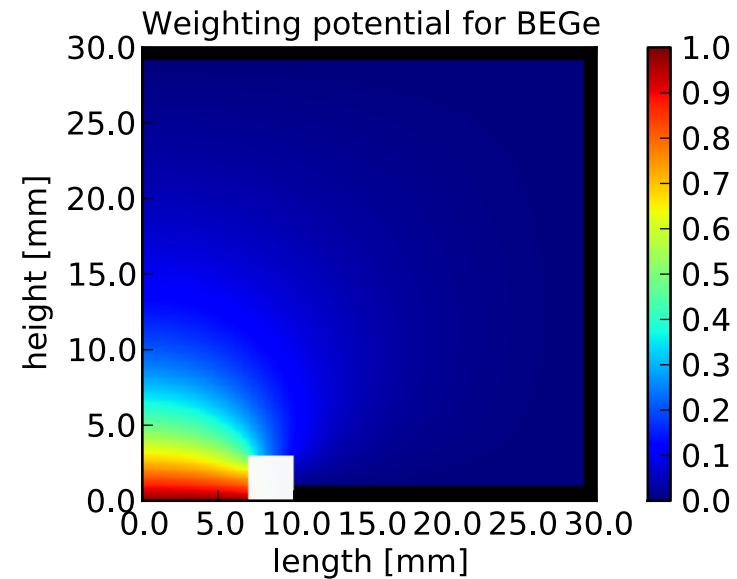
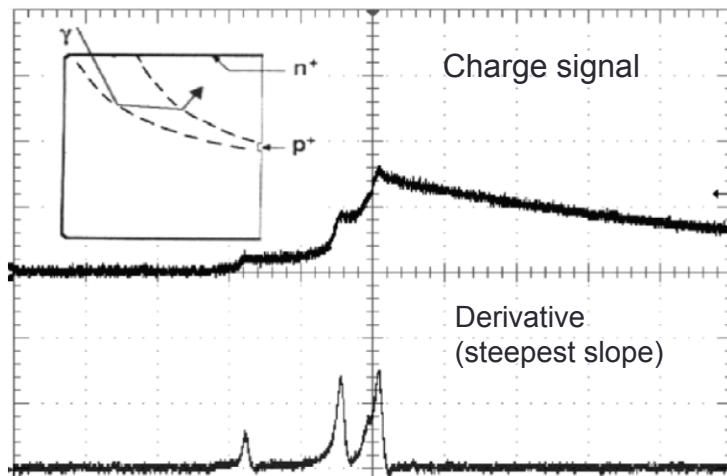
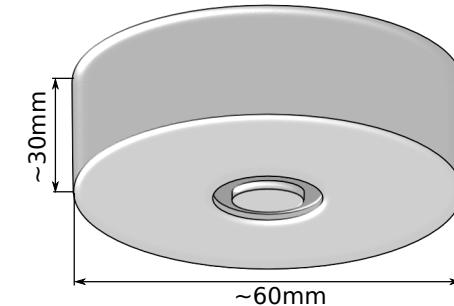


Examples: ADL + GERDA

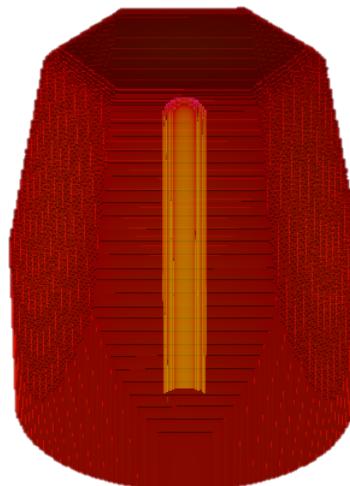


BEGe Broad Energy Ge detector:

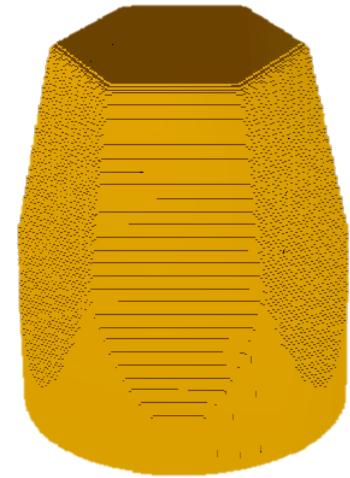
- have a very local weighting potential
- Identification of multiple hits via steepest slope method
- Very small capacity → low serial noise



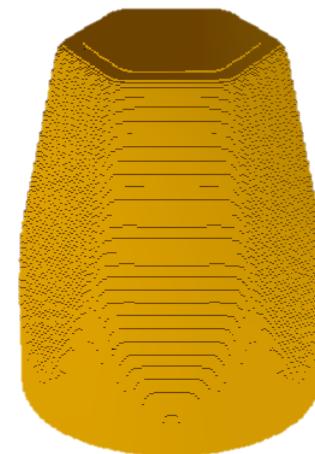
Depletion of a HPGe detector



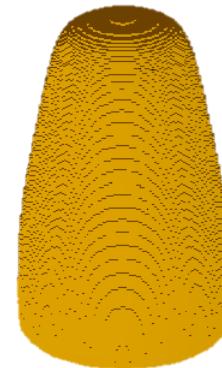
B



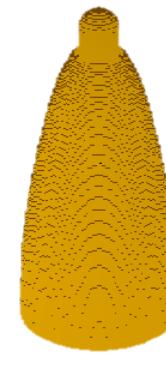
C: HV = 10V



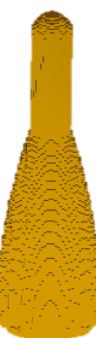
D: HV = 100V



E: HV = 1kV



F: HV = 2kV



G: HV = 3kV

Depletion of a HPGe detector

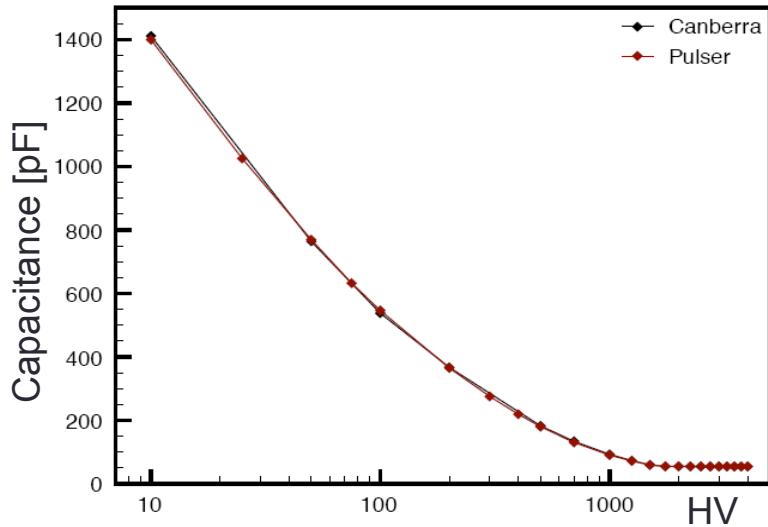
A: Bare HPGe germanium crystal symmetric AGATA detector

B: Geometry in simulation
The HV contact is colored yellow

C-G: Undepleted volume as function of HV.

(assumption: 10^{10} impurities / cm³)

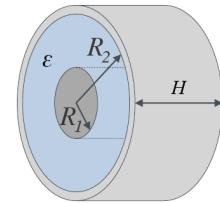
Impurity from C-V measurements



Reconstruction of impurity profile:

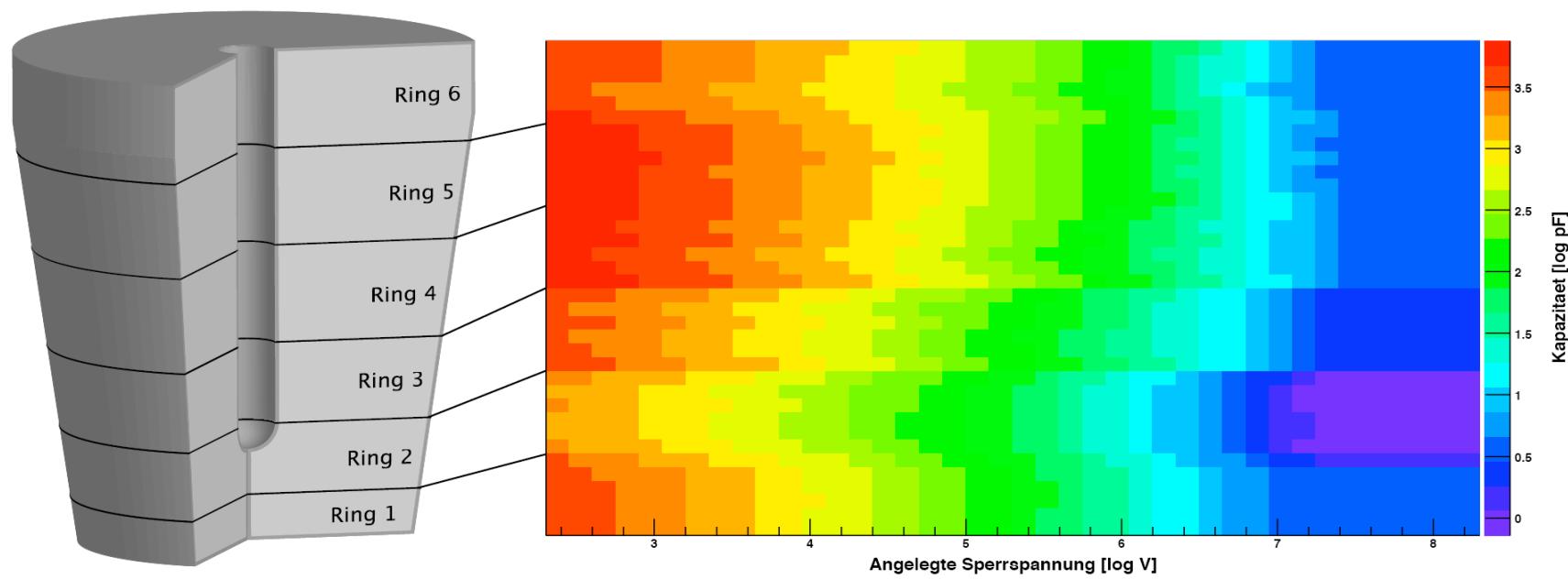
- $C(V)$ gives depletion boundary R_1 :

$$C = \frac{2\pi\epsilon H}{\ln \frac{R_2}{R_1}}$$



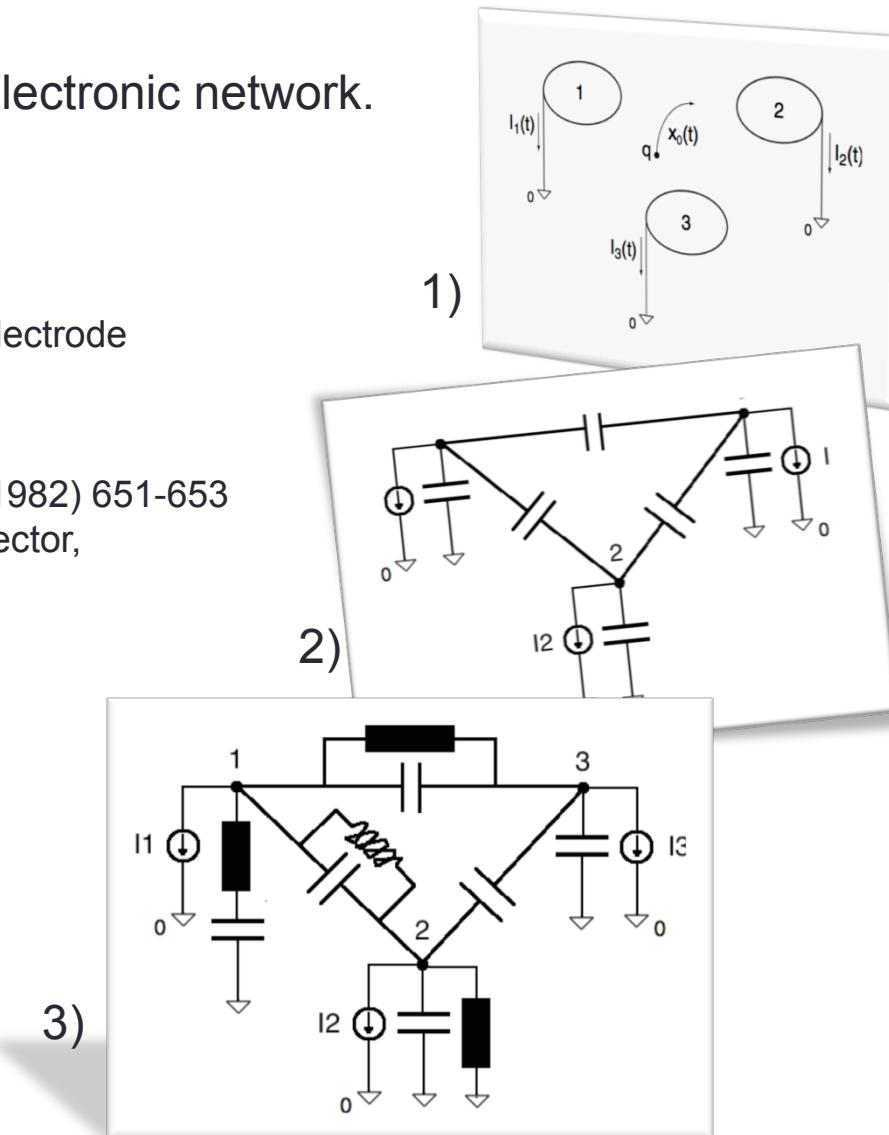
- $C(V)$, dC/dV give impurity concentration at R_1

$$N_D(R_1) = -\frac{C^3 e^{\frac{4\pi\epsilon H}{C}}}{4e\pi^2 H^2 \epsilon R_2^2 \frac{dC}{dV}}$$

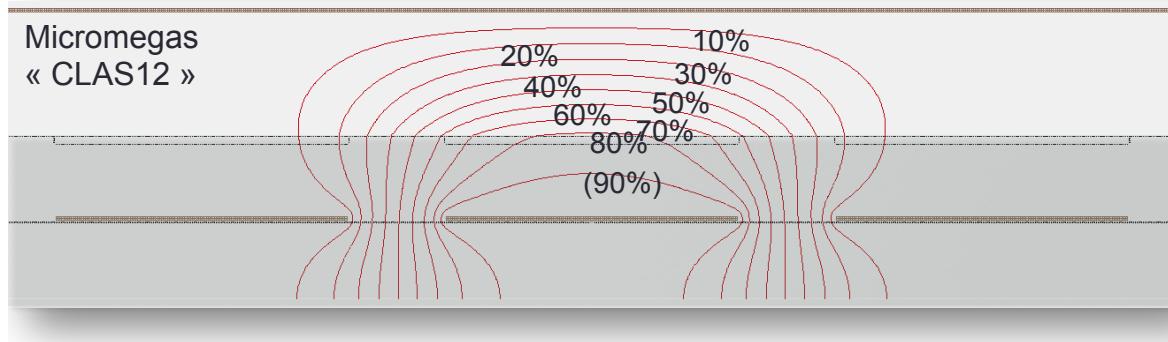


Extended Ramo theorem

- Describes detectors in a realistic electronic network.
- In 3 steps:
 - 1) Apply the Ramo theorem:
Calculate the induced currents in each electrode
 - 2) Equivalent electronics scheme:
Proof: see Gatti and Padivini, NIM 193 (1982) 651-653
-Determine the capacitances of your detector,
-Add the current sources found from 1)
 - 3) Realistic electronics scheme:
Change the above simplified scheme
into a realistic model
- Result = realistic signals



Time dependent weighting potentials



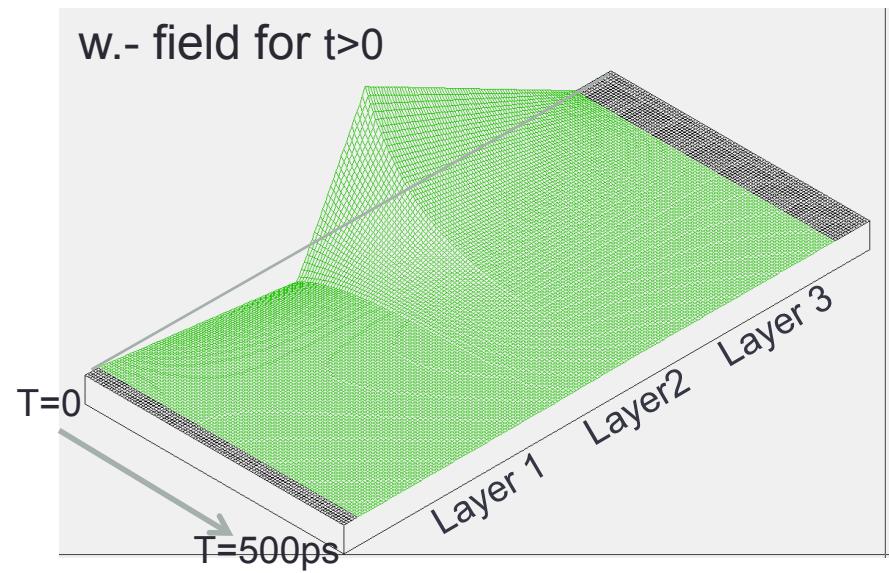
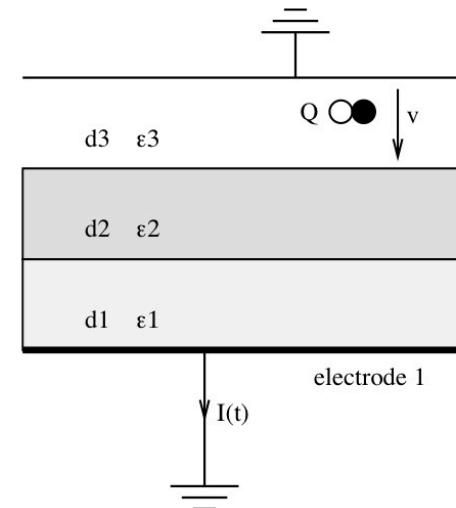
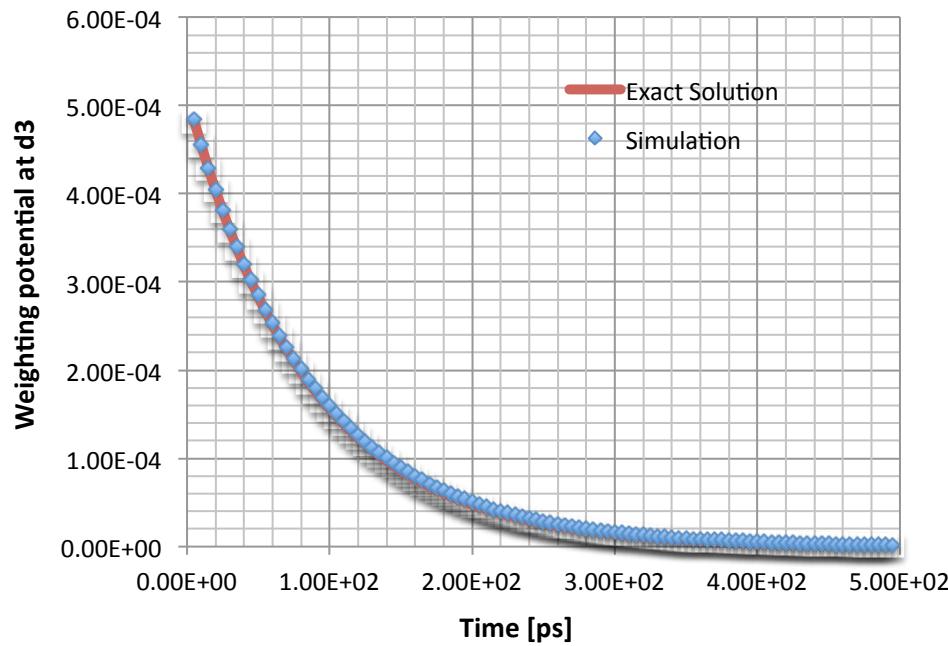
Equation to solve:

- Homogeneous dielectric medium: $\nabla^2 \phi(x) = 0$
- Inhomogeneous medium: $\nabla \varepsilon(x) \nabla \phi(x) = 0$
- Including resistivity : $\nabla(\varepsilon(x) + \sigma(x)/s) \nabla \phi(x, s) = 0$
= Time dependent weighting potential $\phi(x, t)$
↑ Laplace Transform

Ex: Astrobox

Astrobox	d [μm]	ϵ_r	σ [$1/\Omega\text{m}$]
layer 3	80	1	0
layer 2	25	4.5	0.5
layer 1	75	4	0

$$V_3(x, t) = c(x) [\delta_t + (1/\tau_2 - 1/\tau) \exp(-t/\tau)]$$



MOBILITIES IN GERMANIUM

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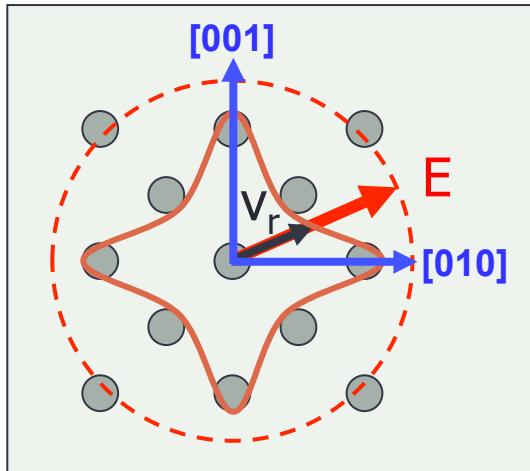


Anisotropic Mobility

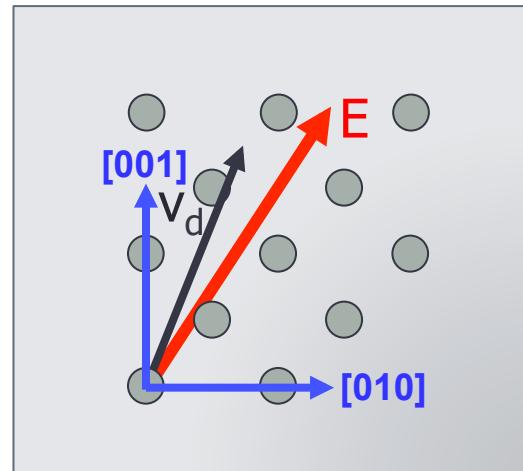
$$\vec{v}_d = \iiint \vec{v}(\vec{k}) f(\vec{k}) d\vec{k}$$

- At high fields, radial anisotropy is observed
- Radial anisotropy induces tangential anisotropy: a drift component towards the faster axis
- For fields along symmetry axis, no tangential drift components can exist: Crystal + E field are then invariant under certain rotations; so must be the drift

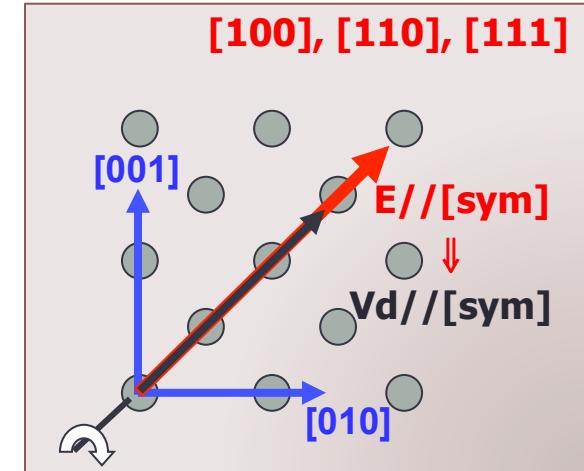
Radial anisotropy,



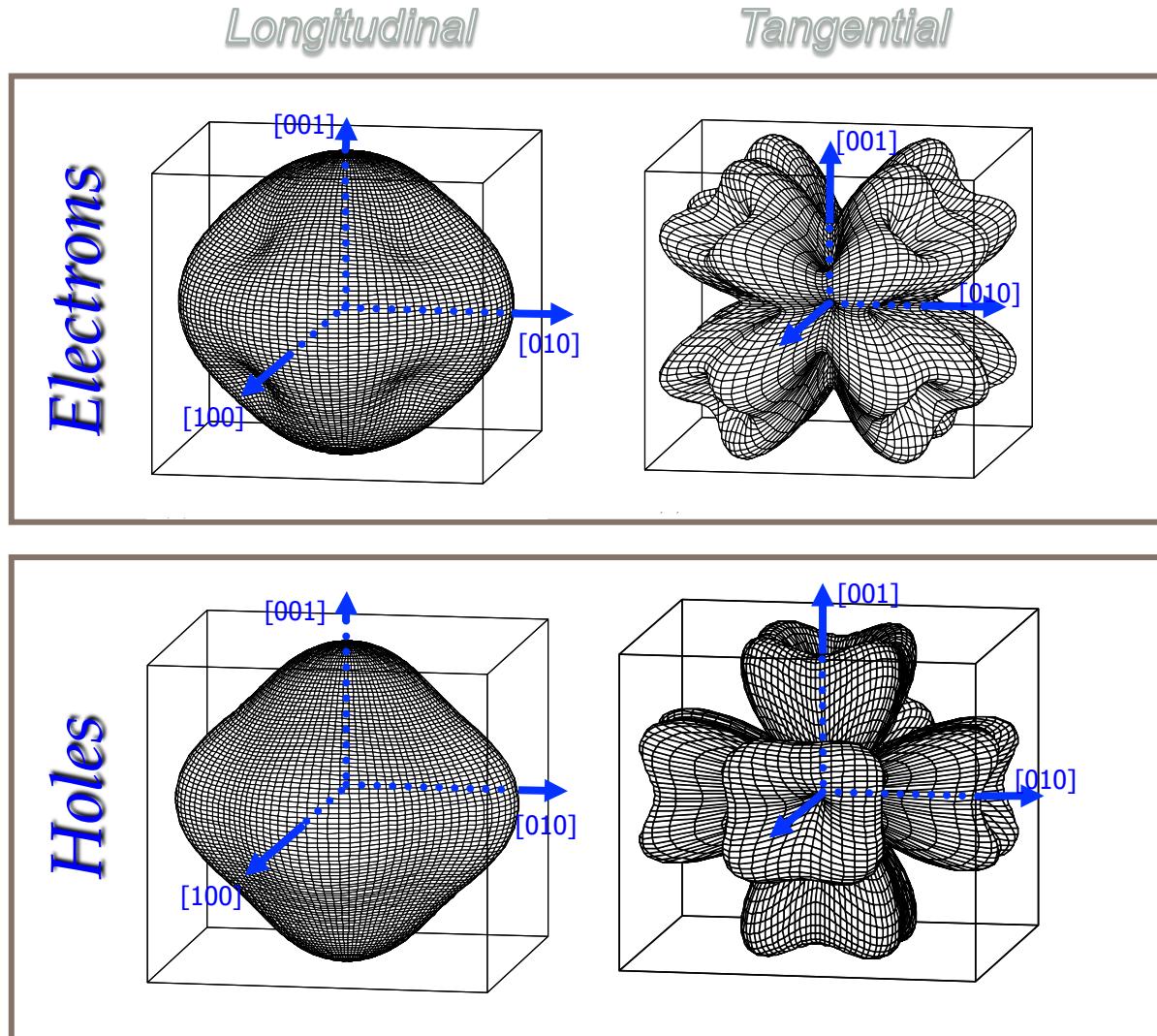
Tangential anisotropy,



except for $E // \text{symmetry axis}$

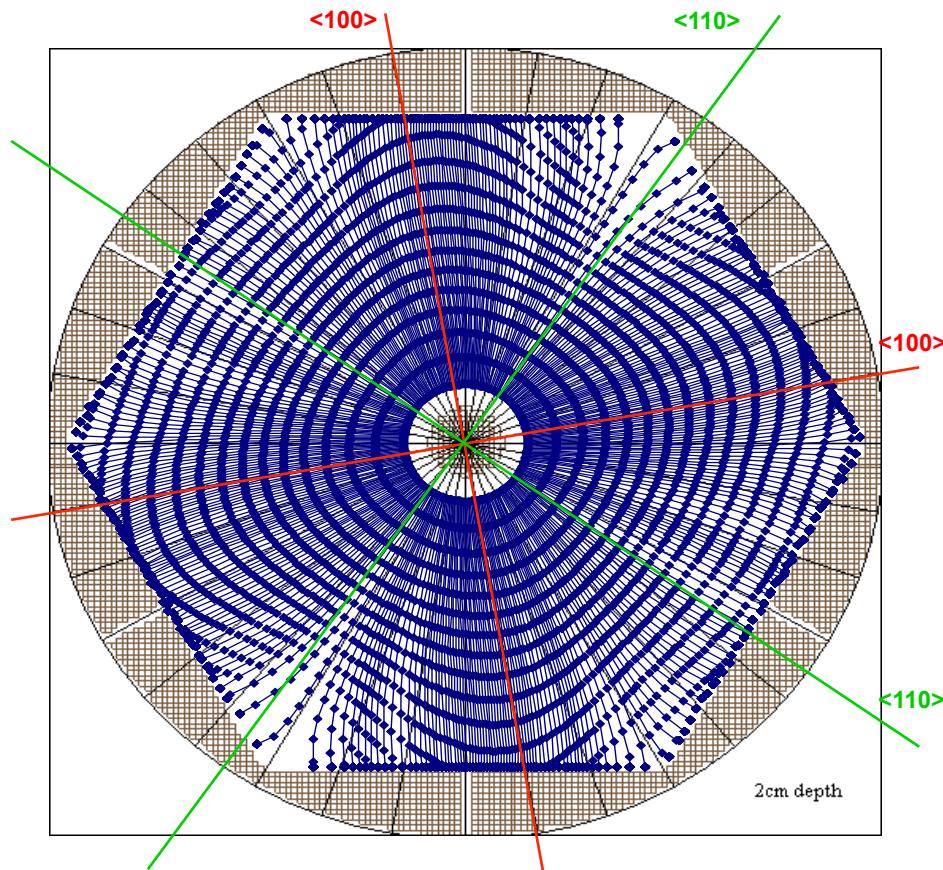


Anisotropy in mobility

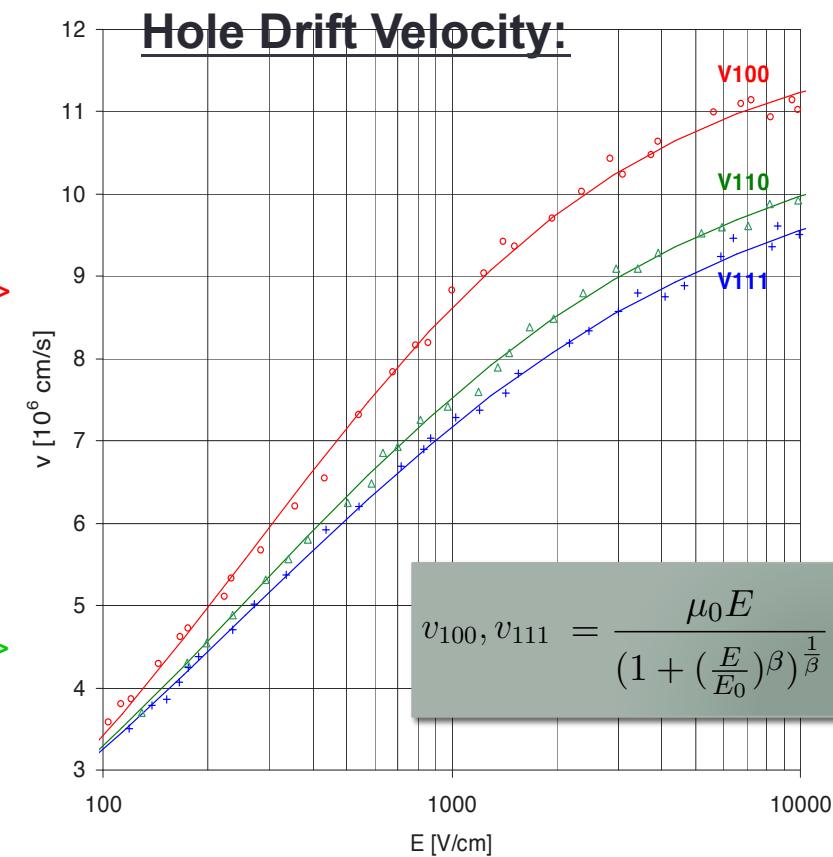


- Longitudinal and tangential components of drift velocity as function of orientation of the field (1200 V/cm)
- Electrons v_r mainly slower near [111],
- Holes v_r mainly faster near [100]
- Tangential components:
 - 0 along symmetry axes
 - pointing towards nearest [100] axis

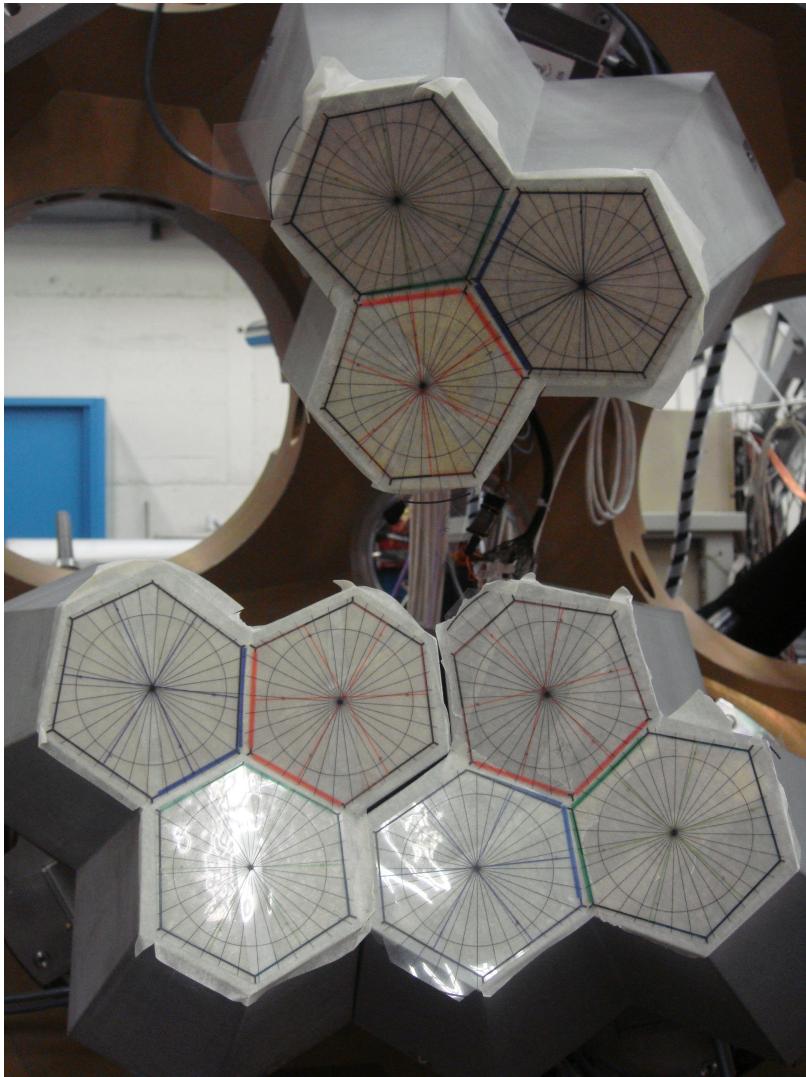
Example: Hole trajectories



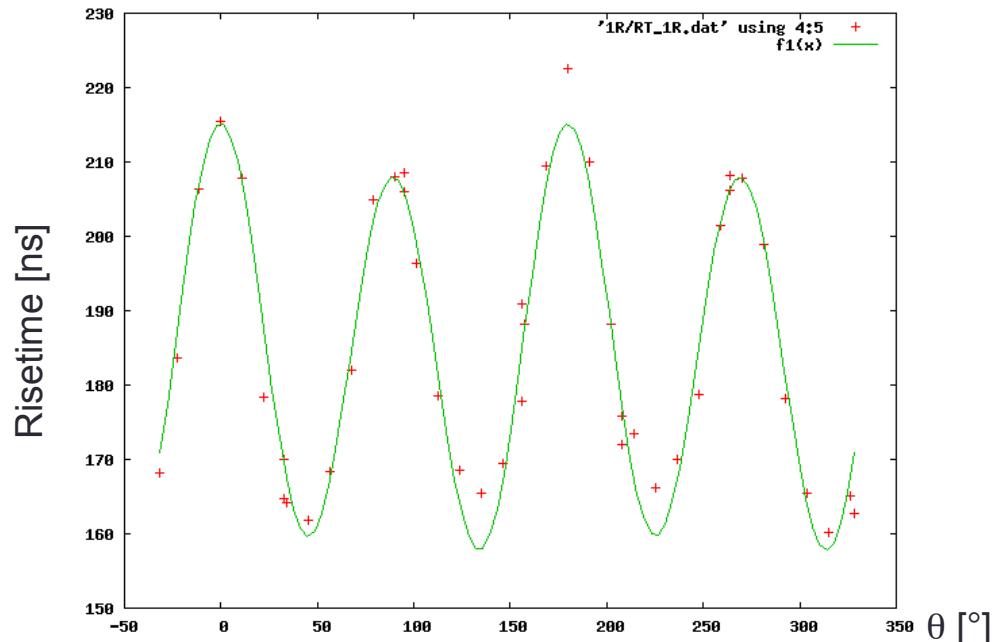
Hole trajectories for homogeneous starting positions around the core electrode. Every 25ns a point was plotted on the trajectory



Measuring the crystal axis

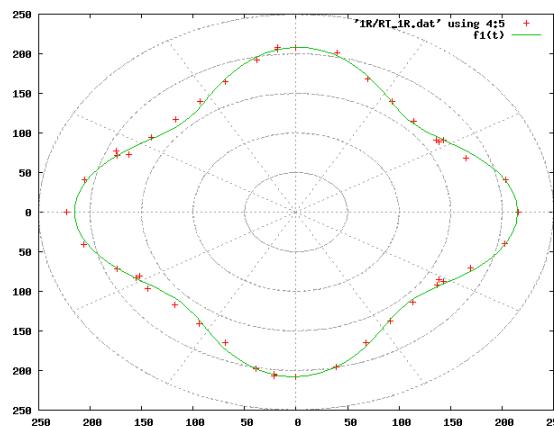


- 400 kBq Am source +
- Lead Collimator: \varnothing 1.5mm X 1cm
- Front Scan at \varnothing 4.7cm: 300 cts/s
- Fitfunction Risetime(θ) =
$$A.[1+R_4\cos(\theta-\theta_4)].[1+R_2\cos(\theta-\theta_2)]$$

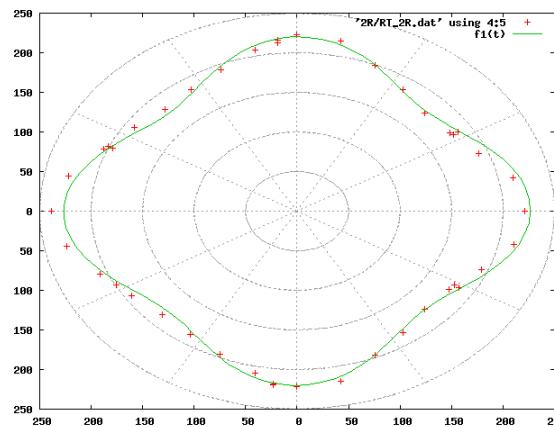


ATC1

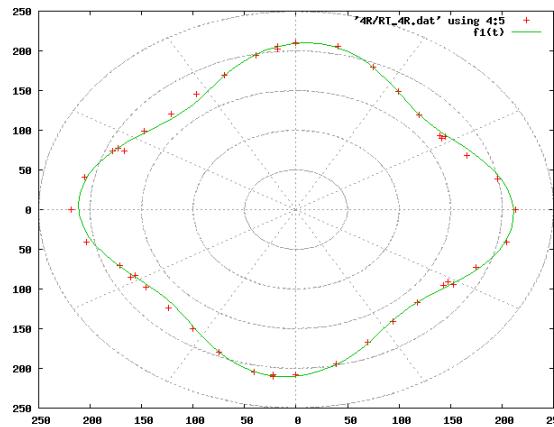
R



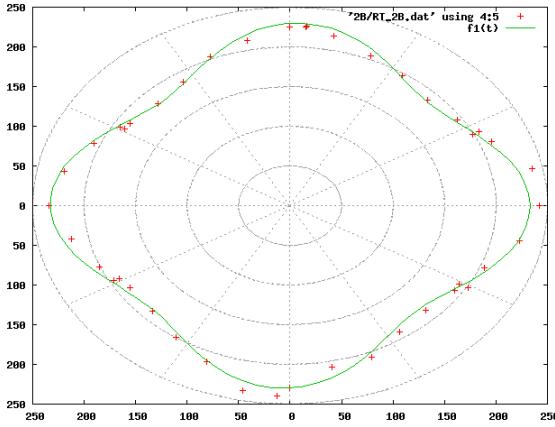
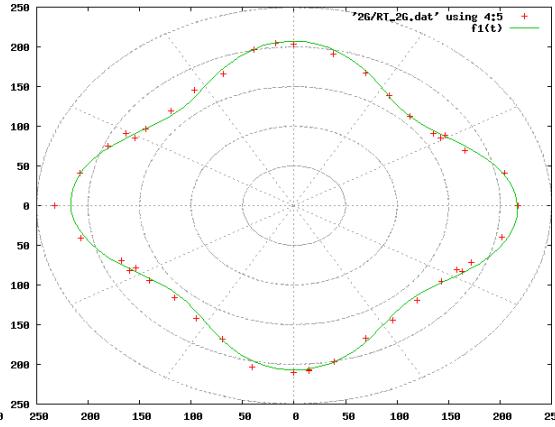
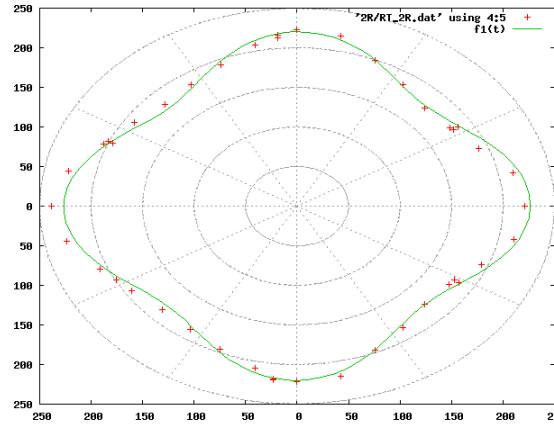
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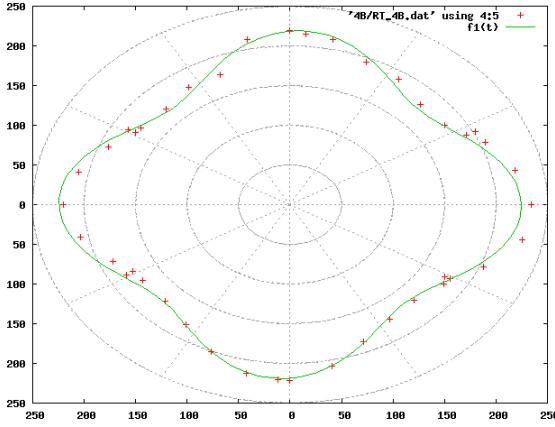
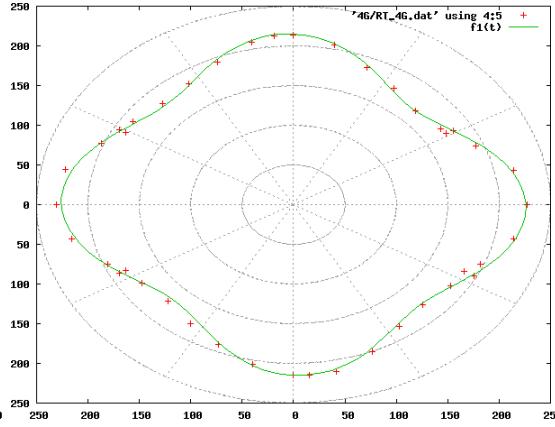
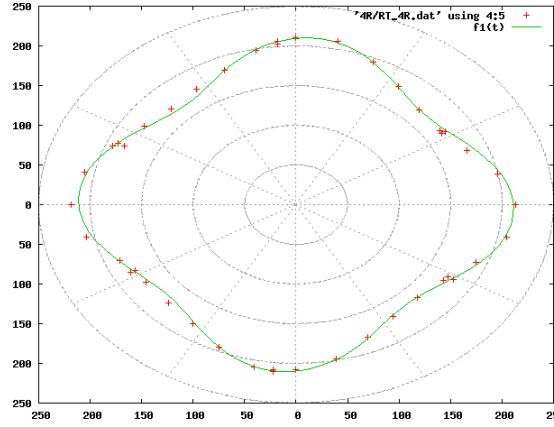
B



ATC2

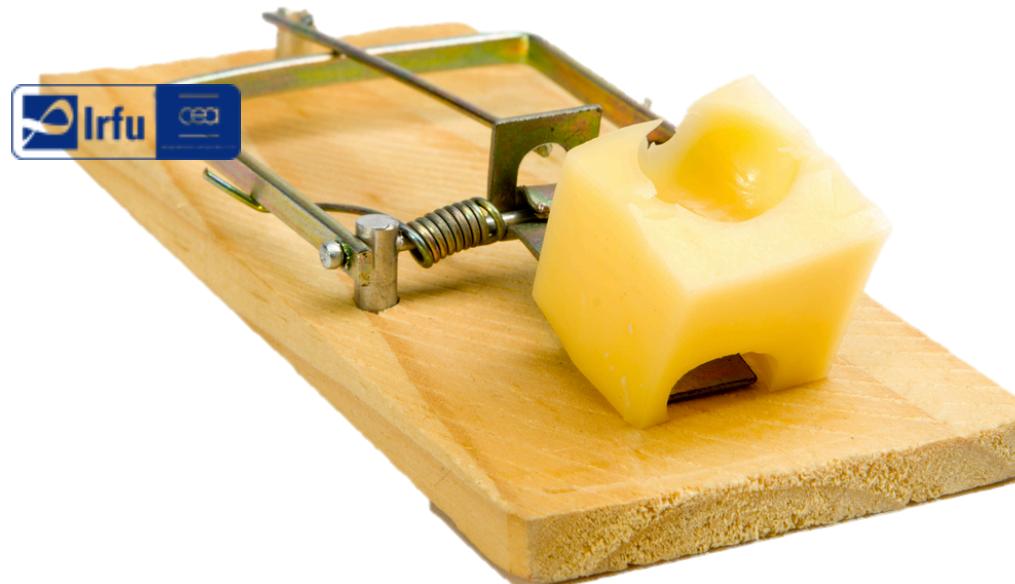


ATC4

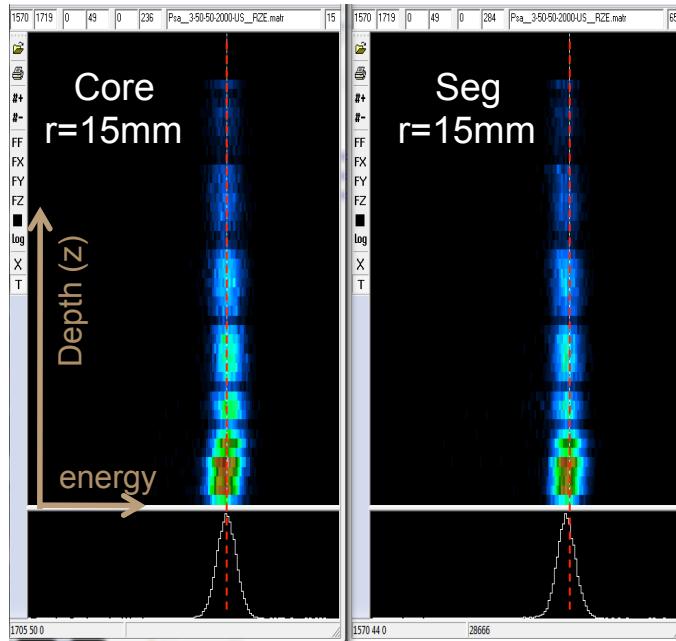


NEUTRON DAMAGE, TRAPPING AND CORRECTION

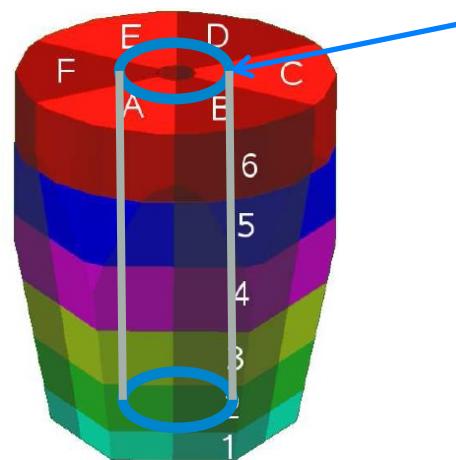
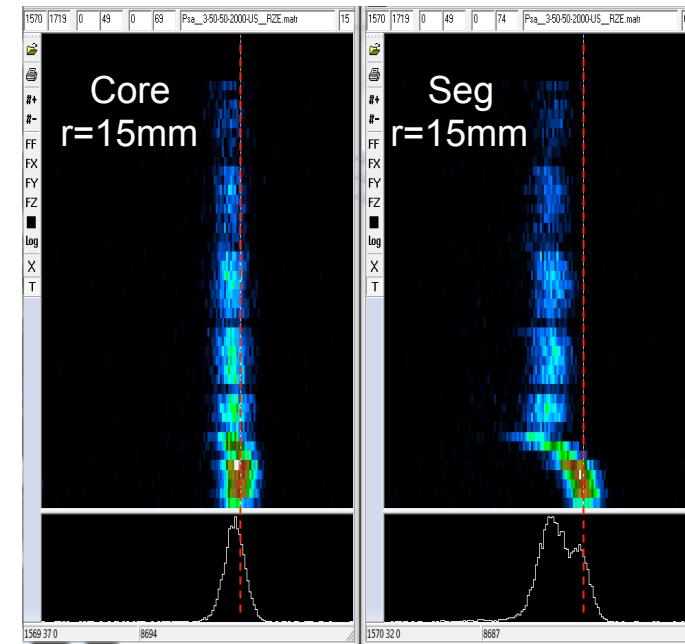
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New detector...



after neutron damage



The 1332 keV peak as a function of crystal depth (z) for interactions at $r = 15\text{mm}$

The charge loss due to neutron damage is proportional to the path length to the electrodes. This is provided by the PSA, which is barely affected by the amplitude loss.

Knowing the interaction position,
the charge trapping can be modeled and corrected away

Collection Efficiency

T.W. Raudorf, R. H. Pehl – NIM A 255 (1987) 538-551

Bruyneel et al. – EPJ A (2013) 49:61

- Trapping rate of electrons / holes “q”:

$$\frac{dq}{dt} = - <\sigma v> N_t q \Leftrightarrow q(t) = q_0 \cdot e^{-\int_0^t <\sigma v> N_t dt'}$$

σ : trapping cross section
 v : microscopic velocity
 $<.>$: average over ensemble
 N_t : density of trapping centers

- Collection efficiency (position dependent) of electrons / holes for electrode “i”:

$$\eta_{e,h}^i(\vec{x}_0) = - \int_0^{t_e} (\vec{\nabla} \phi_i \cdot \vec{v}_{e,h}) \cdot \frac{q(t)}{q_0} dt$$

x_0 : interaction position in detector
 ϕ_i : weighting potential of segment i
 $v_{e,h}$: drift velocity of electrons / holes
 t_e : collection time

= Integral [current to seg i per unit charge]
= total recorded charge by e/h after collection

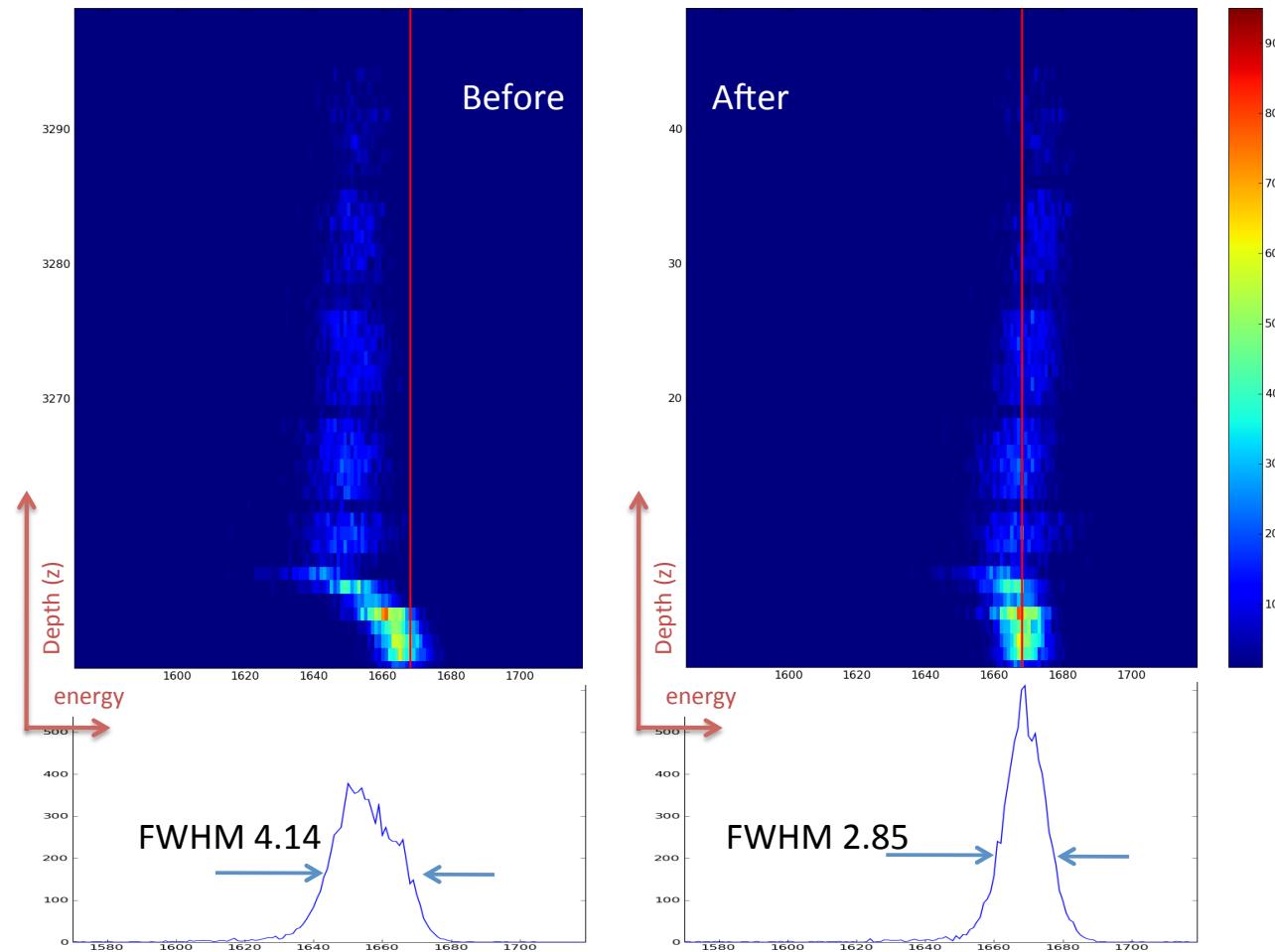
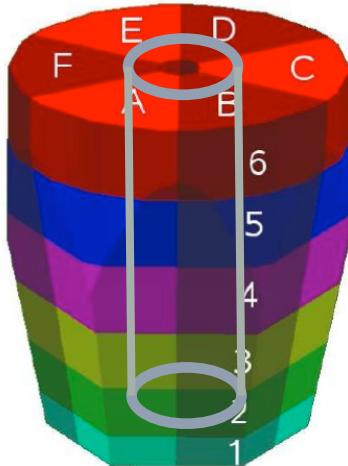
- Total collection efficiency allows reconstruction of original energy:

$$\eta_{tot}^i(\vec{x}_0) = \eta_e^i(\vec{x}_0) + \eta_h^i(\vec{x}_0)$$

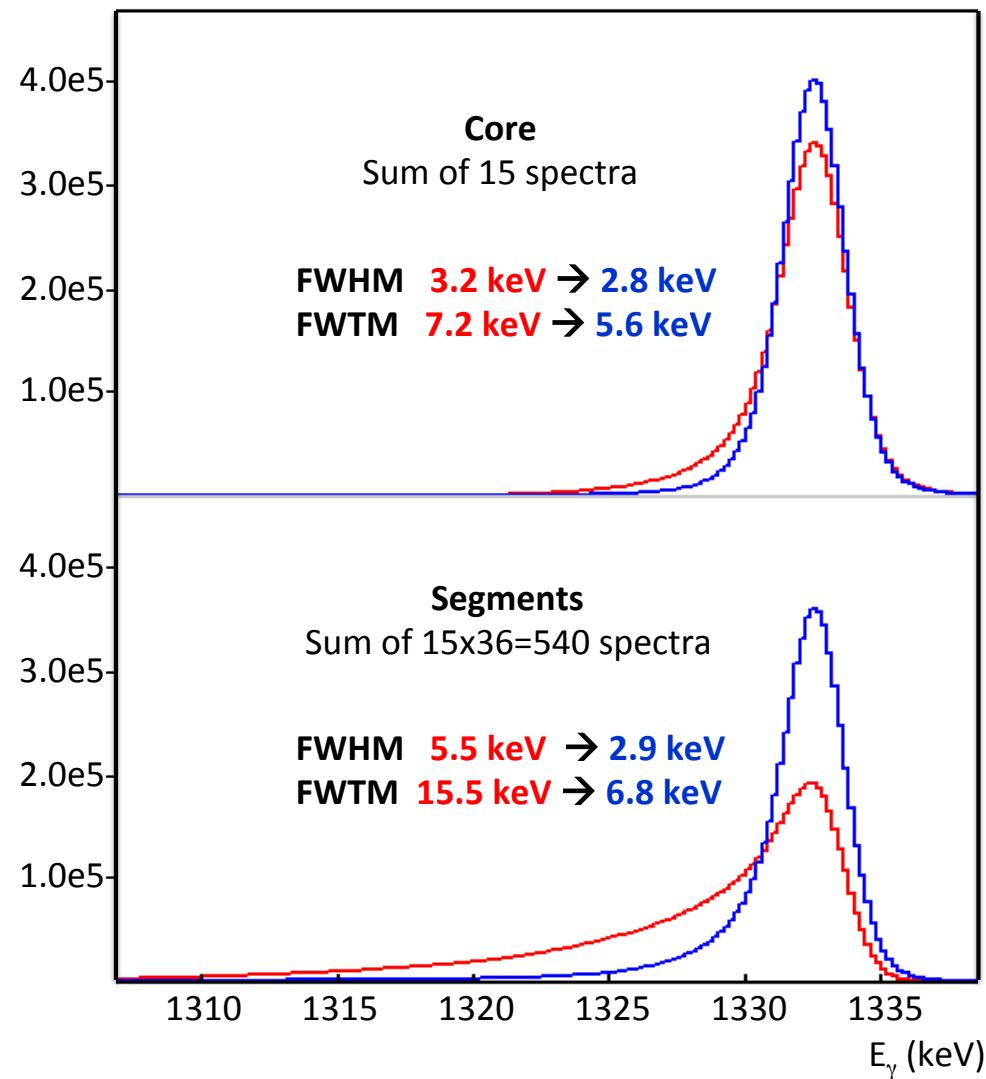
Neutron Damage Correction

The 1332 keV peak as a function of crystal depth (z)
for interactions at $r = 15\text{mm}$

Selection of events using PSA



Neutron Damage Correction



Line shape at the end of the AGATA @ LNL beam campaign

- Red = without correction
Blue = with correction
- summed core line shape:
Core is rather insensitive to neutron damage
- Summed segments line shape:
Segments are more sensitive to neutron damage than core.

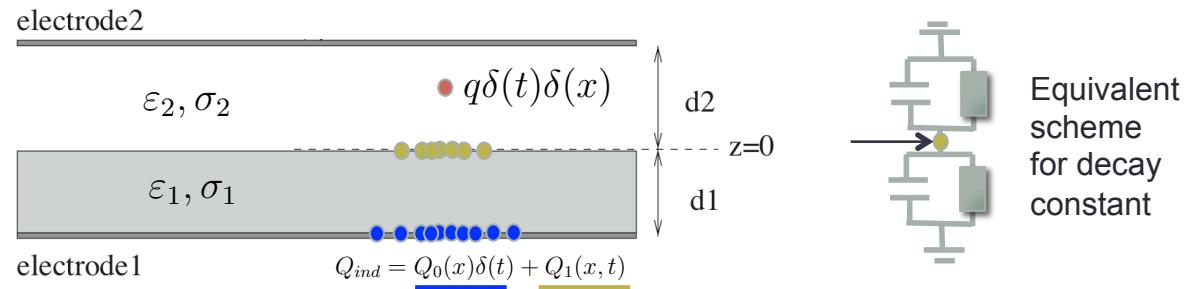
...FIN...

Bart Bruyneel
CEA Saclay, France



Time dependent weighting potentials

An example:



- Infinite short times:
directly induced charges,
time independent fraction of weighting potential

$$\lim_{s \rightarrow \infty} \nabla(\varepsilon(x) + \sigma(x)/s) \nabla \phi(x, s) = 0$$
- q also charges the interface at $z=0$:
indirectly induces charges
time evolution of the charges at interface
- Total Weighting potential

$$\phi = \underline{\phi_0(x)\delta(t)} + \underline{\phi_1(x, t)}$$
- Time integrated charge:

$$\phi_{int} = \int_0^\infty \phi \, dt \quad \leftrightarrow \lim_{s \rightarrow 0} \nabla(\varepsilon(x) + \sigma(x)/s) \nabla \phi_{int}(x, s) = 0$$

Example: Astrobox

Explicit solution for $x < d_3$:

see e.g. W. Riegler, NIM A 491 (2002) 258

define

$$a = \varepsilon_1 \varepsilon_2 d_3 + \varepsilon_2 \varepsilon_3 d_1 + \varepsilon_3 \varepsilon_1 d_2$$

$$b = \varepsilon_3 \sigma_2 d_1 + \varepsilon_1 \sigma_2 d_3$$

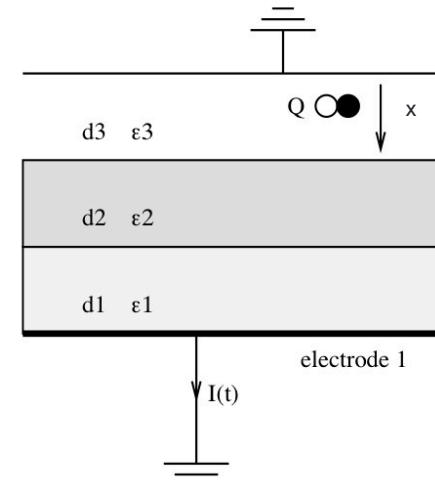
$$c(x) = \varepsilon_1 \varepsilon_2 x / a$$

$$\tau_2 = \varepsilon_2 / \sigma_2$$

$$\tau = a / b$$

$$V_3(x, s) = c(x) \frac{s + 1/\tau_2}{s + 1/\tau}$$

$$V_3(x, t) = c(x) [\delta_t + (1/\tau_2 - 1/\tau) \exp(-t/\tau)]$$

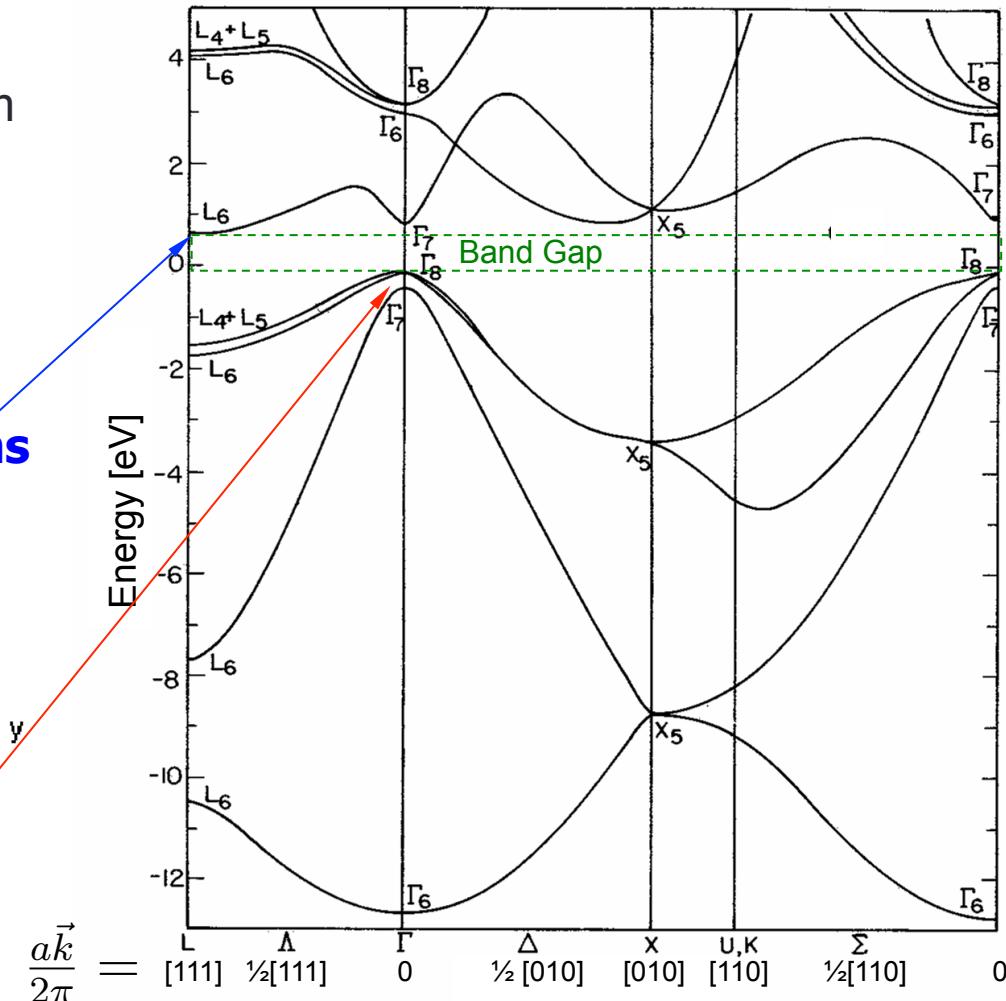
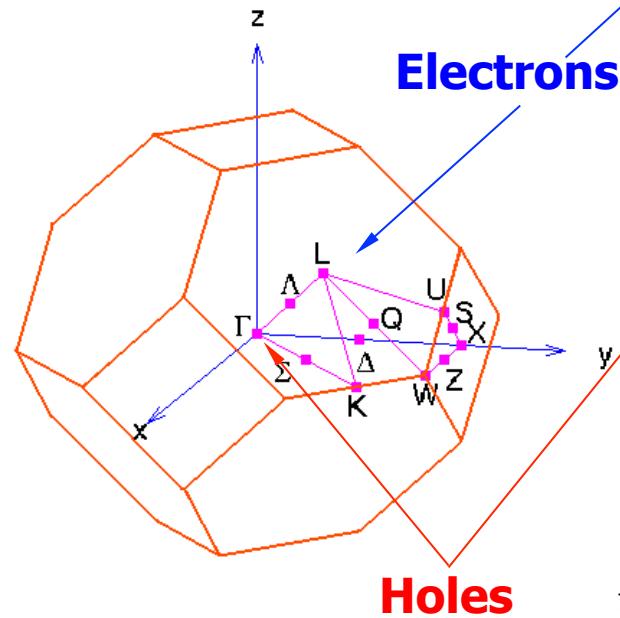


Astrobox	d [μm]	ε_r	σ [$1/\Omega\text{m}$]
layer 3	80	1	0
layer 2	25	4.5	0.5
layer 1	75	4	0

Germanium Band structure

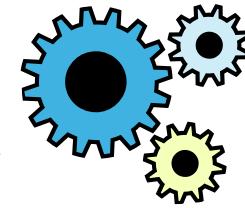
first Brillouin zone:

- Electrons populate minimum of conduction band
- Holes populate maximum of valence band

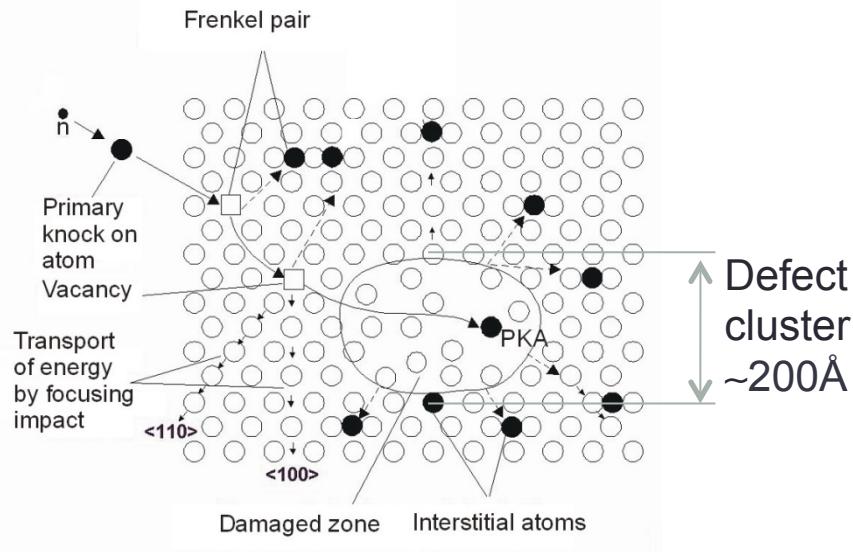


Trapping cross section

L. S. Darken et al. NIM 171 (1980)

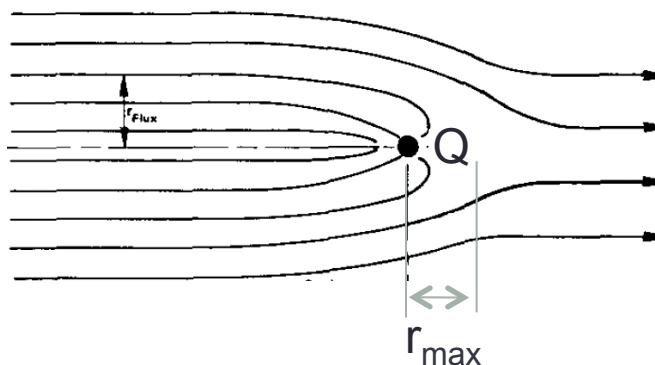


Damage by fast neutrons:



Cross section from field line disturbance:
Balance between E field and Coulomb force:

$$qE = \frac{Qq}{4\pi\epsilon r_{max}^2} \Leftrightarrow \sigma \propto 4\pi r_{max}^2 = \frac{Q}{\epsilon E}$$



Assumptions:

- Trapping only by disordered regions
 - Macroscopic model: drift velocity!
- $Q \sim 100e$ equilibrium charge state
 $r_{max} \sim 2 \mu m$ cross section ($E=2kV/cm$)
 $I_e \sim 0.2 \mu m$ dist. betw. optical phonon emission

Trapping rate (per hole):

$$\langle \sigma v \rangle \propto \frac{v_d}{E}$$

Reconstructed Impurity Profile

